



The ATLAS ITk Strip Detector System for the Phase-II LHC Upgrade

George Iakovidis

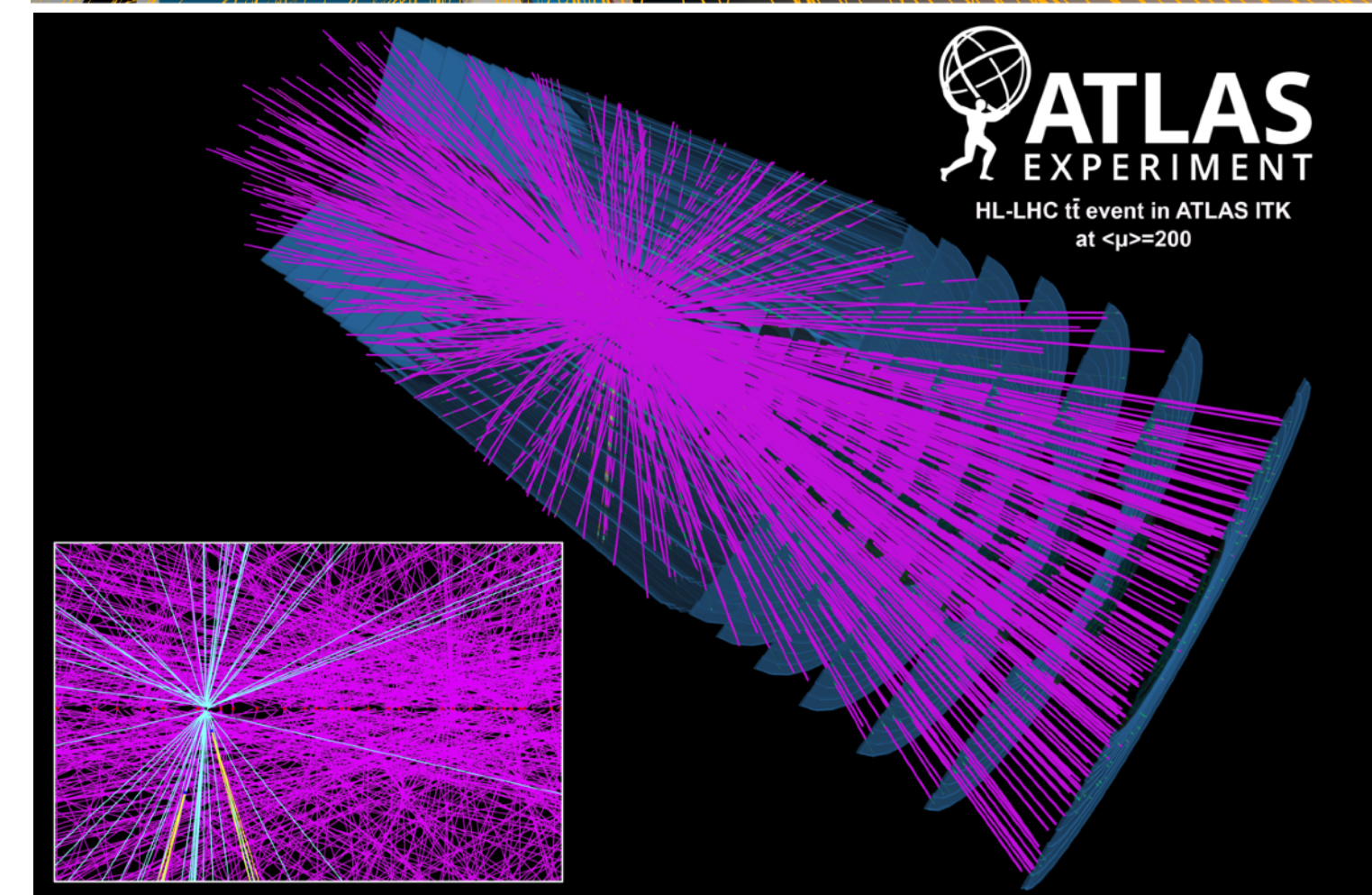
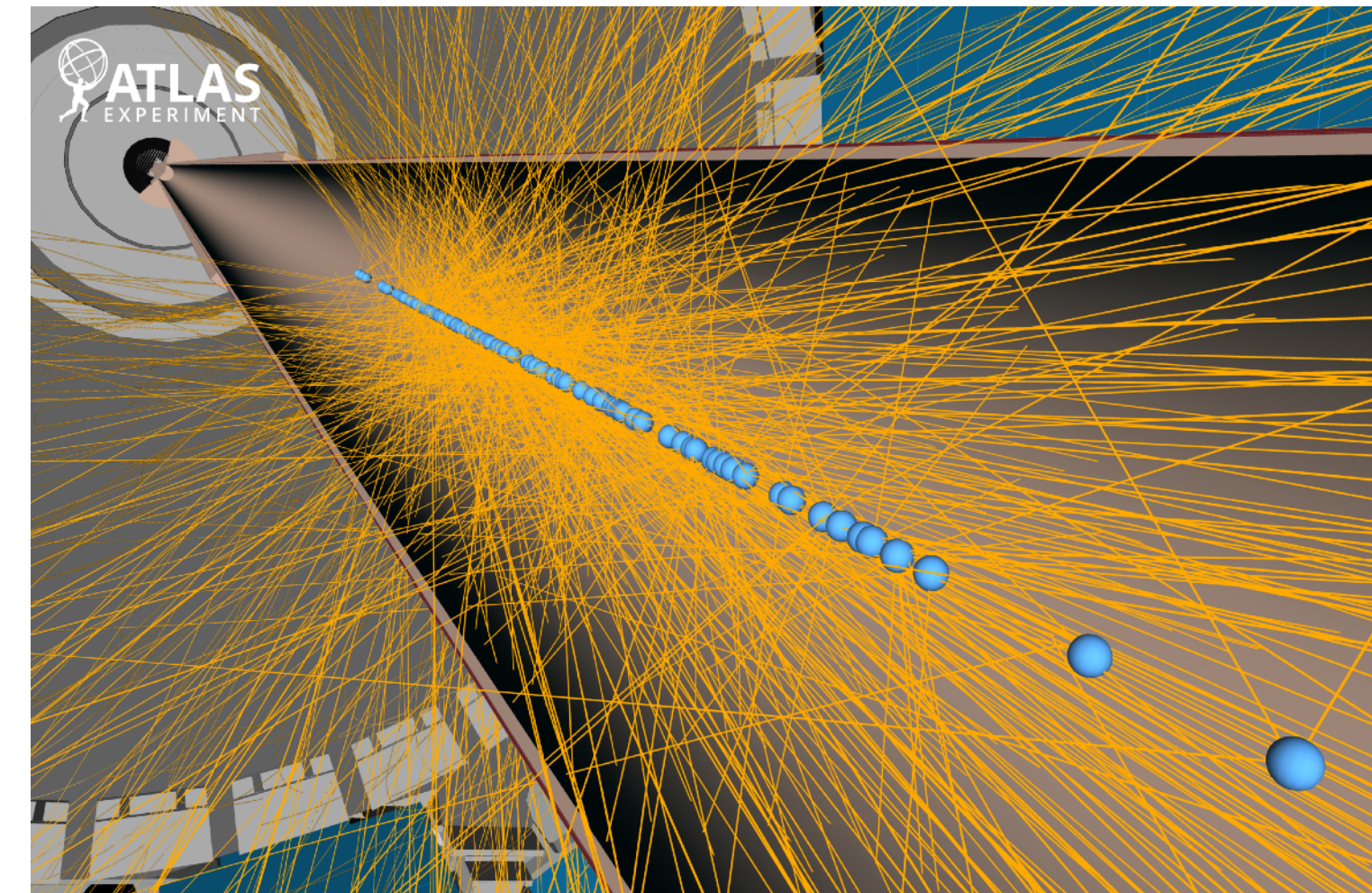
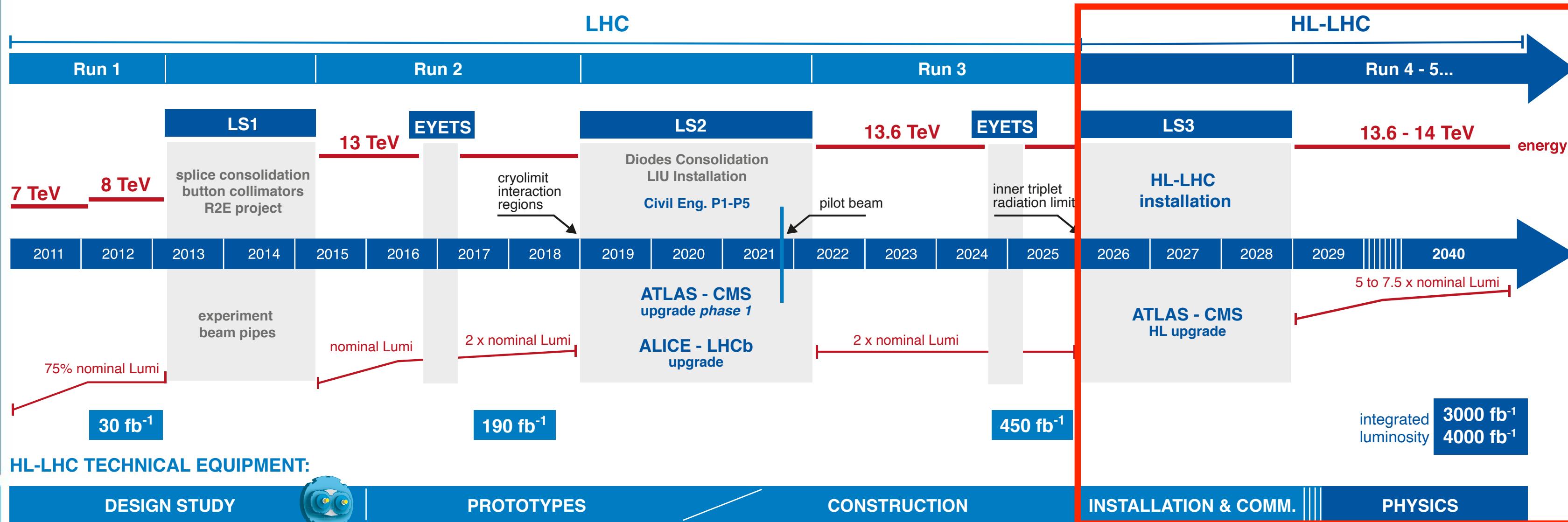
on behalf of the ATLAS ITk Strips community

*13th International "Hiroshima" Symposium on the Development and Application of Semiconductor Tracking Detectors (HSTD13)
Dec 3 – 9, 2023 - Vancouver, Canada*

High Luminosity - LHC

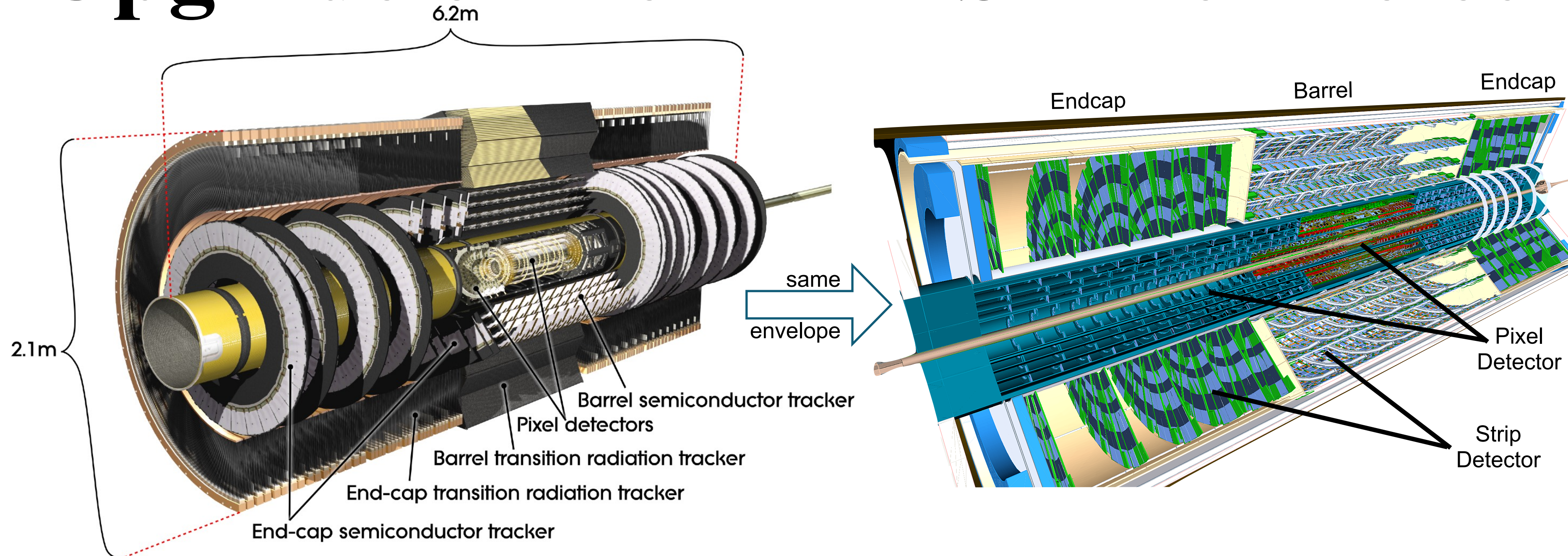
High Luminosity (HL)-LHC will bring **major** changes to the detector's environment:

- **Luminosity** increase up to $\mathcal{L} = 5 - 7.5 \times 10^{34} \text{ cm}^{-1}\text{s}^{-1}$
- **Integrated Luminosity** up to 3000 – 4000 fb^{-1}
- Up to 200 inelastic pp collisions per beam crossing (**pileup**)
- Increased luminosity \rightarrow ~ 10 times higher **radiation**
 - \rightarrow **Harsh environment** for the tracker



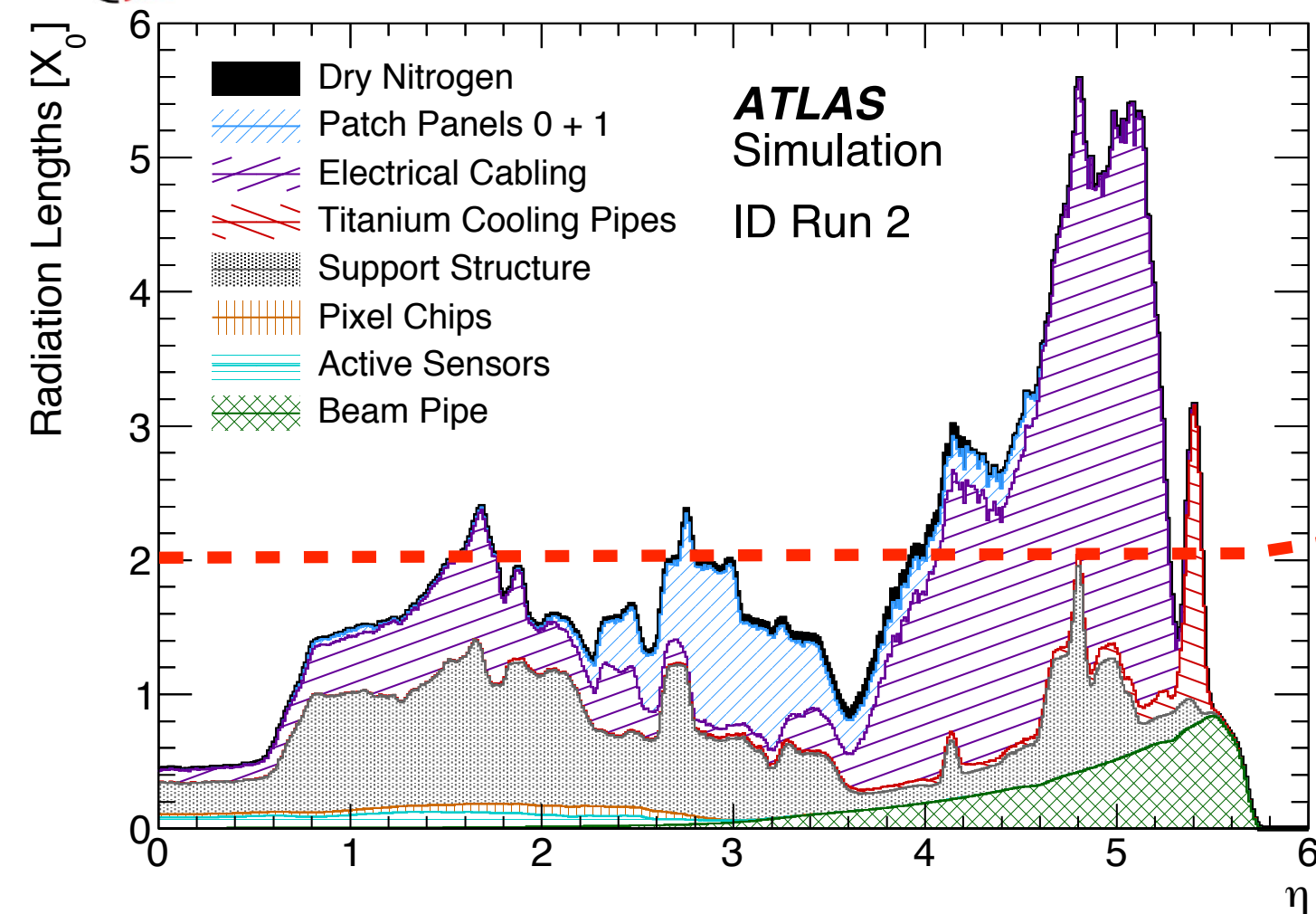
Event Displays from Upgrade Physics Simulated Data

Upgrade of the ATLAS Inner Detector

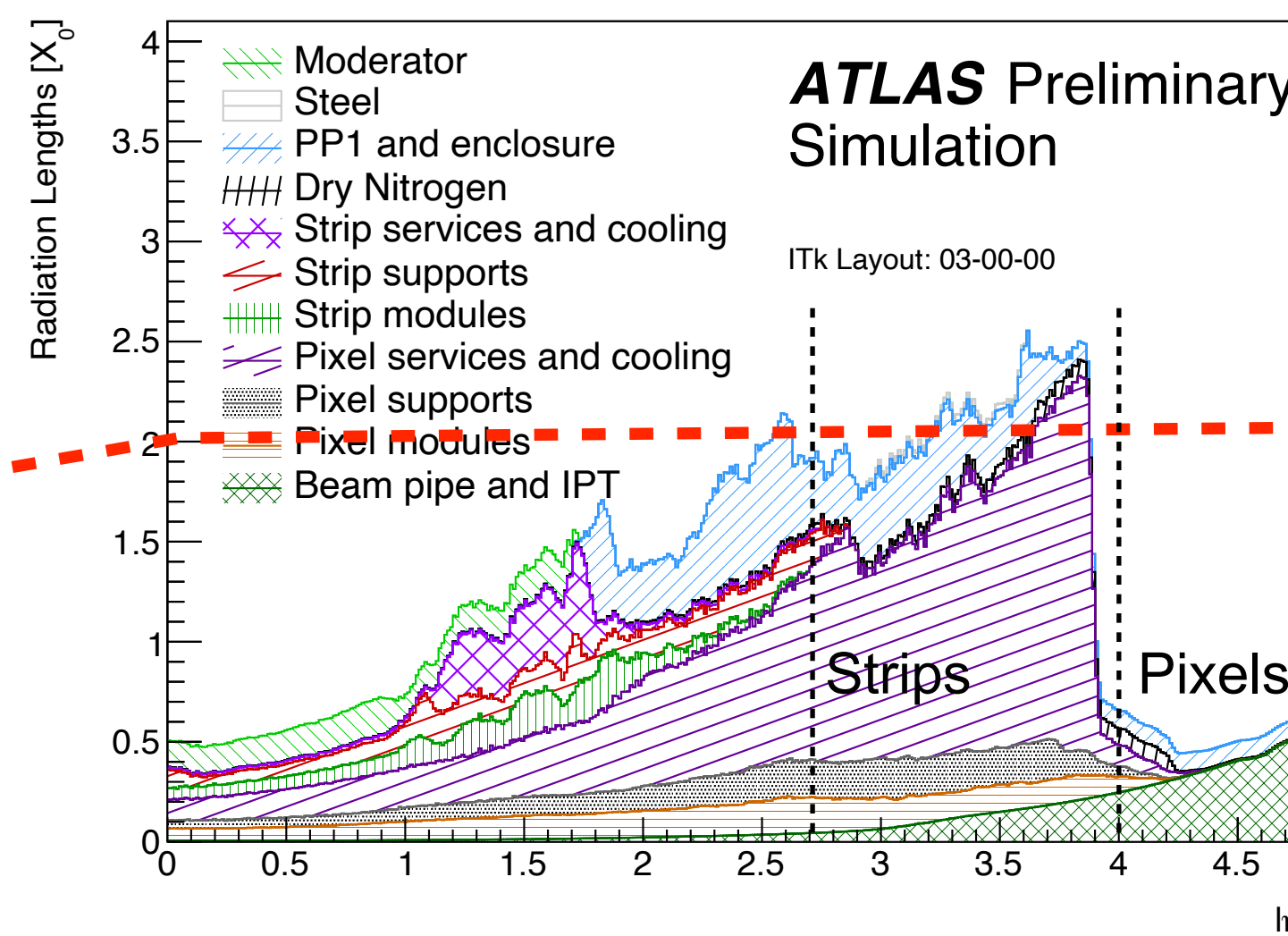


The ATLAS Inner Tracker (**ITk**) to replace the existing Inner Detector

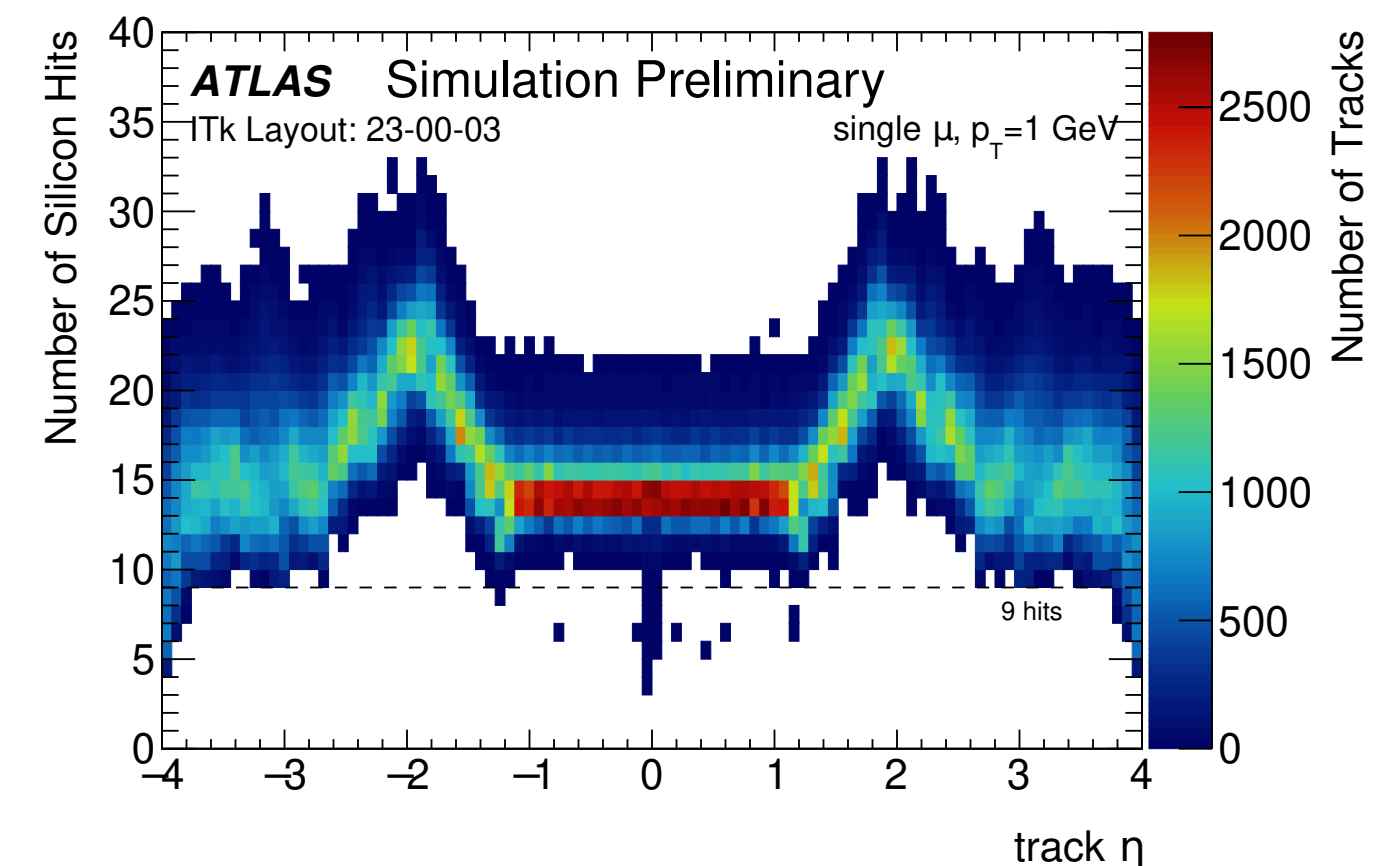
- **All silicon** - Pixels and Strips
- Higher **radiation** tolerance
- Finer **granularity** (# of channels) larger **coverage**
- **Faster** response
- **Reduced material budget**



Current Inner Detector

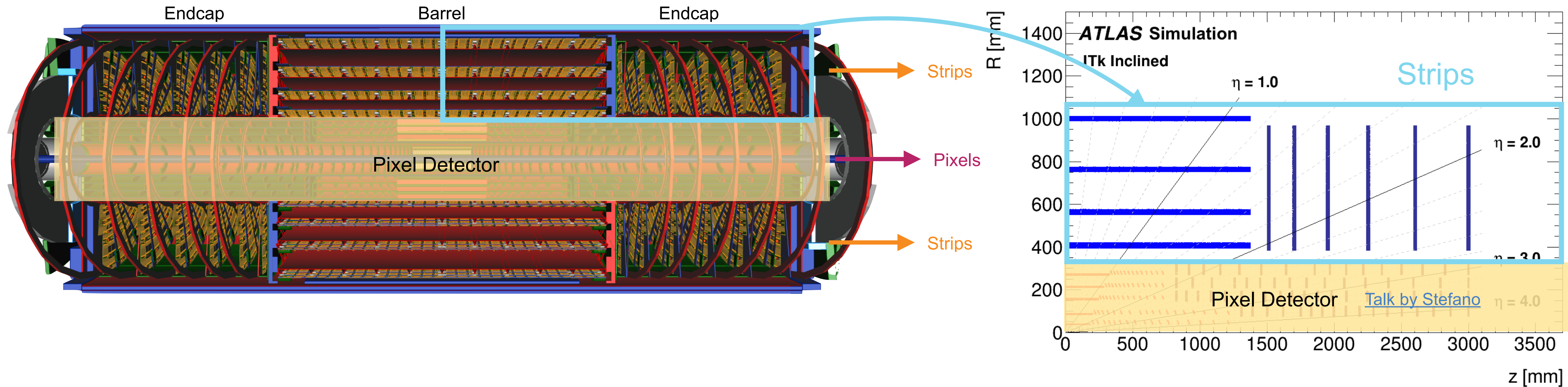


ITk



Coverage up to $\eta = \pm 4$ with at least 9 space points per track

The ITk Strips Layout



Barrel : 4 layers (double sided)

- L3/L2 (outer layers) with long strip (**LS**) staves
- L1/L0 (inner layers) with short strip (**SS**) staves
- Up to ~ 33 MRad **dose** and $7.2 \times 10^{14} n_{eq}/cm^2$

Endcap(s) : 6 disks (double sided) per endcap

- Disk0-Disk5: 32 identical petals on each disk
- Variable pitch and length due to geometry
- Up to ~ 50 MRad dose and $1.2 \times 10^{15} n_{eq}/cm^2$

Strips	# of Layers	# of Detectors	Surface [m ²]	Channels [M]	Strip Pitch [μm]	Strip Length [mm]
Barrel	4	392 Staves	104.86	37.85	75.5	24.1 - 48.2
Endcap	6	384 Petals	60.4	22.02	69 - 85	19 - 60
Total		776	165.25	59.87 M		

The ITk Strip Sensors

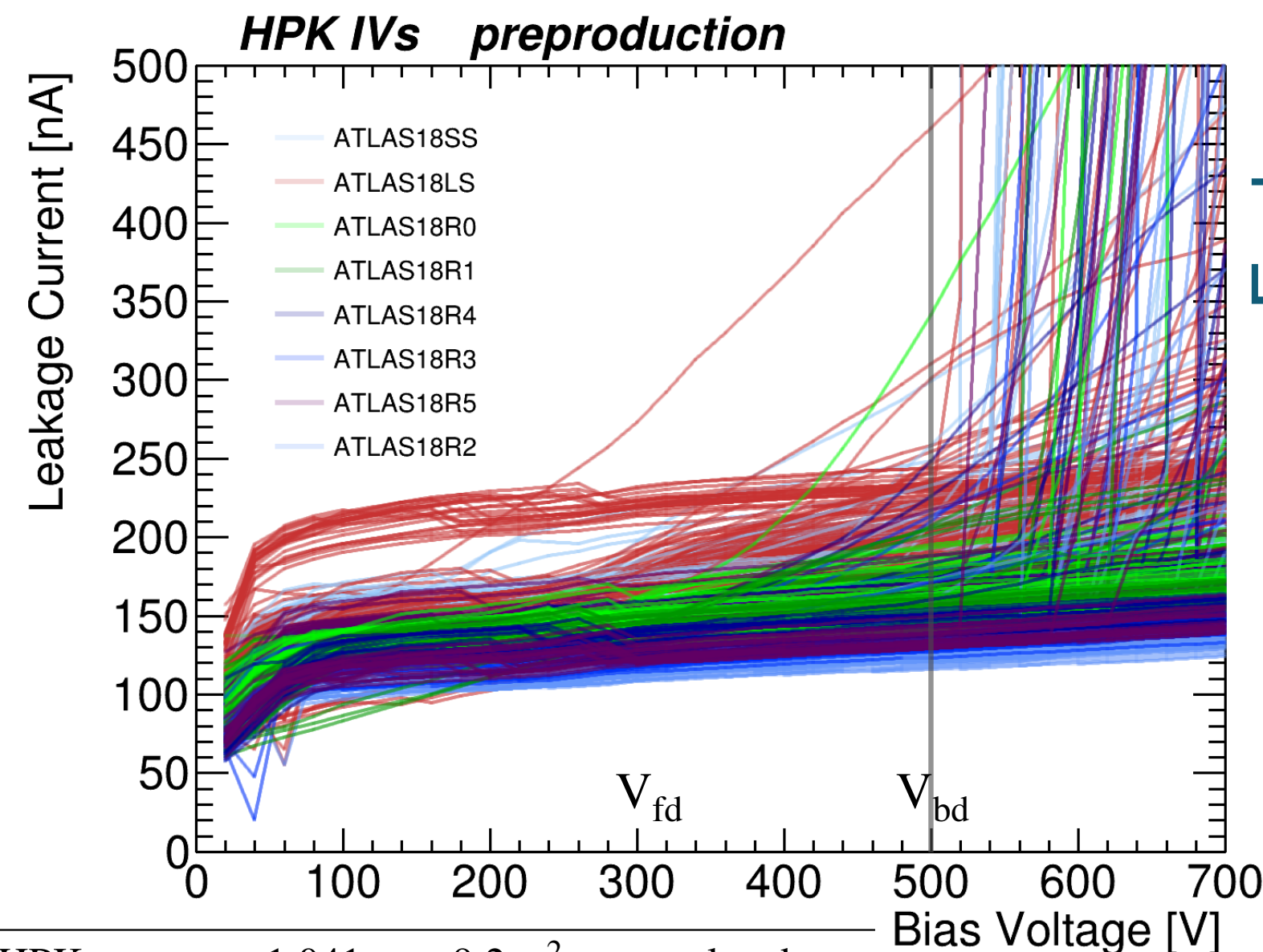
[Poster on Sensor Characteristics by Javier](#)

[Talk by Luise on Curing early breakdown in silicon strip sensors with radiation](#)

- Silicon: **n-type implants in a p-type float-zone silicon bulk** ($n^+ - in - p$) with aluminum AC-coupled strips
- **Produced** by Hamamatsu Photonics K.K. (HPK) in 6-inch, 320 μm thick wafers
- **2 variants** for barrel, 6 variants for endcap(s)
- Miniature sensors, test structures, monitor diodes, and other structures are laid out in the “**halfmoons**”
 - ➔ **Validating** the characteristics/performance of the sensors
- **Operating bias voltage** is set to backplane at -500 V (0 V on n^+) at $\sim -30^\circ\text{C}$

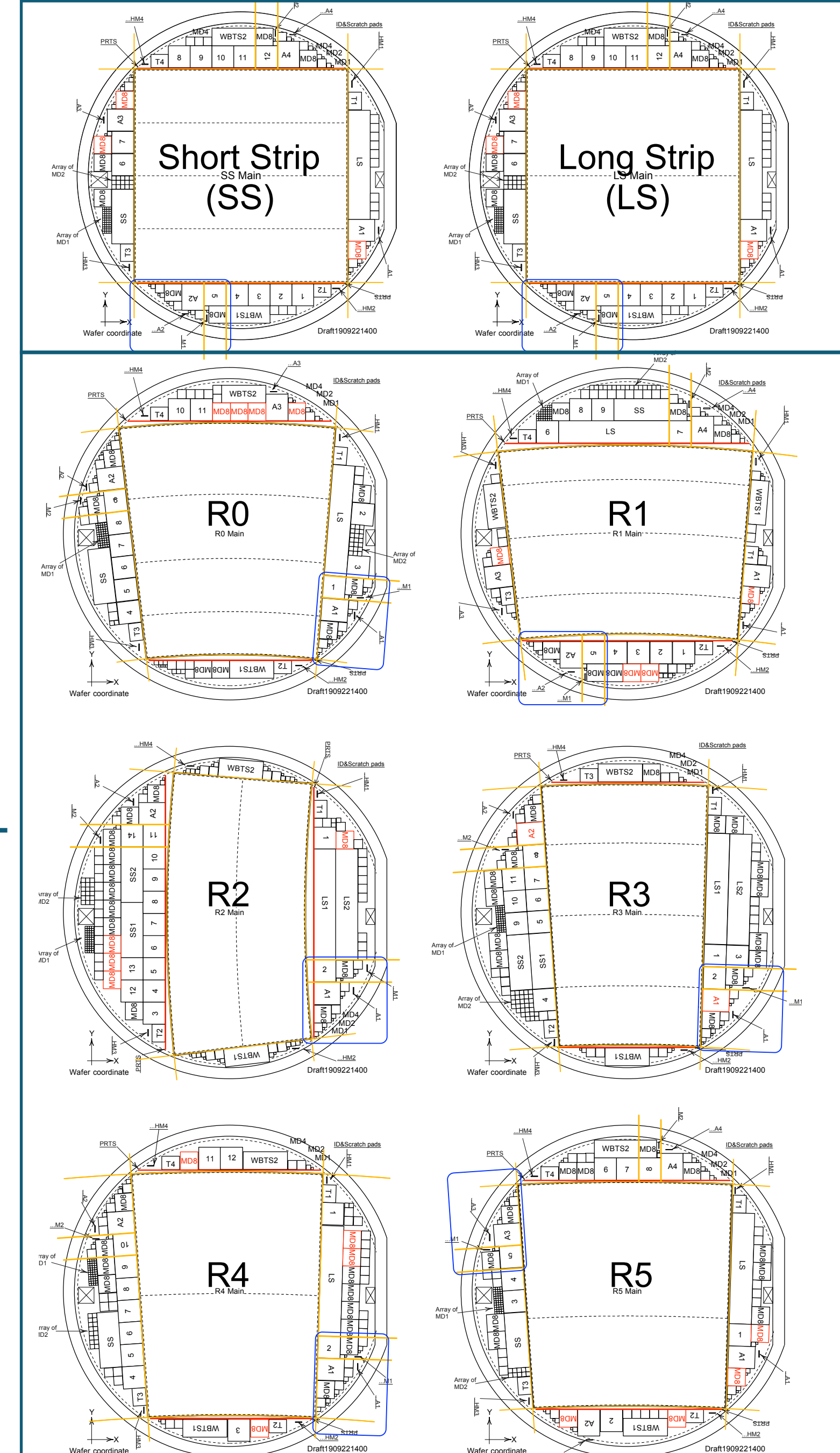
HPK performs **initial tests** against the specifications

- **Visual** inspection edge chipping and scratches
- **Electrical** tests such as Overall capacitance (C-V) and the leakage current (I-V)
- Pre-production (1041 sensors - 5%) showed that **quality** of the sensors “as produced” is **excellent**.



Barrel

Endcap



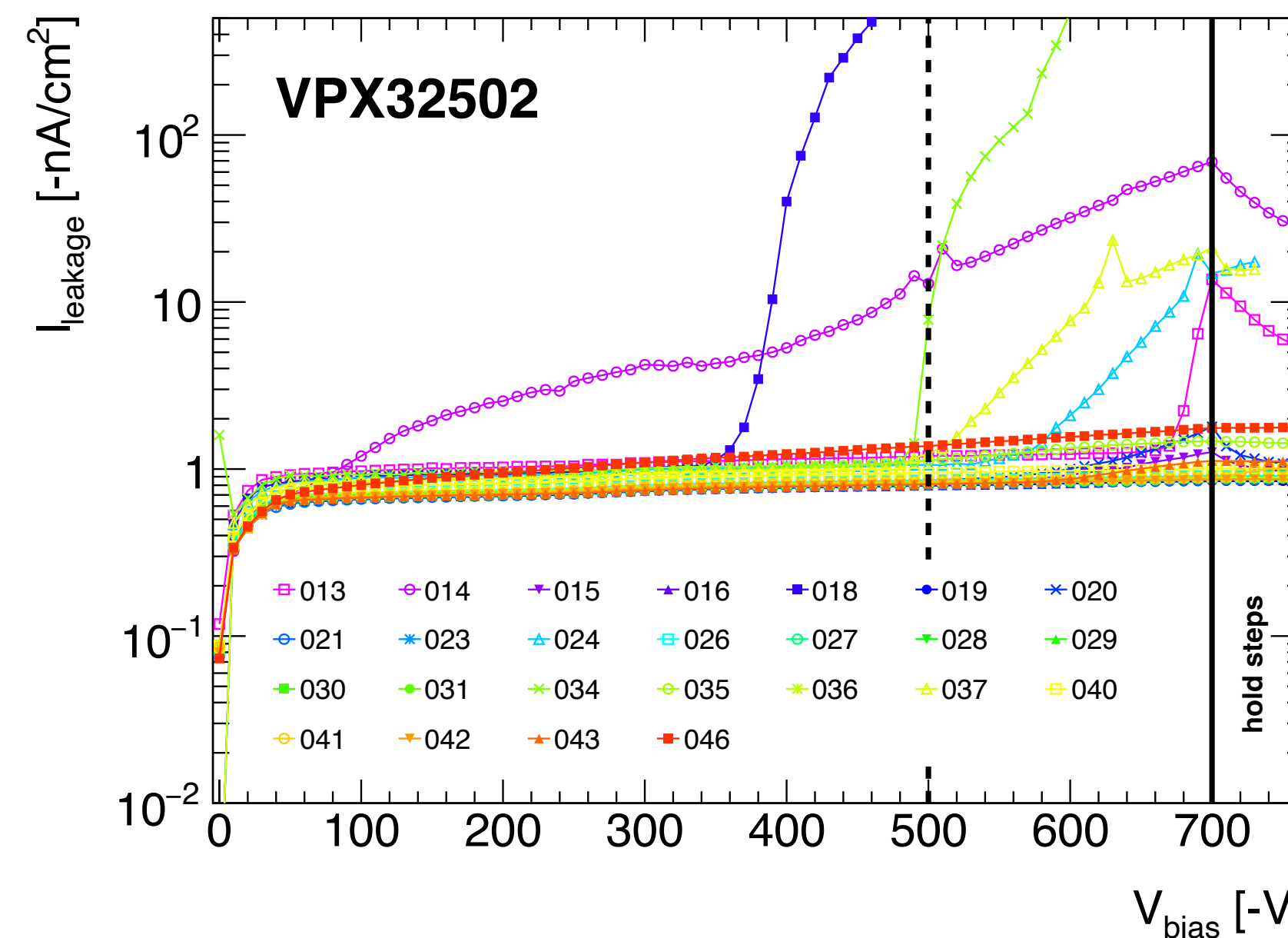
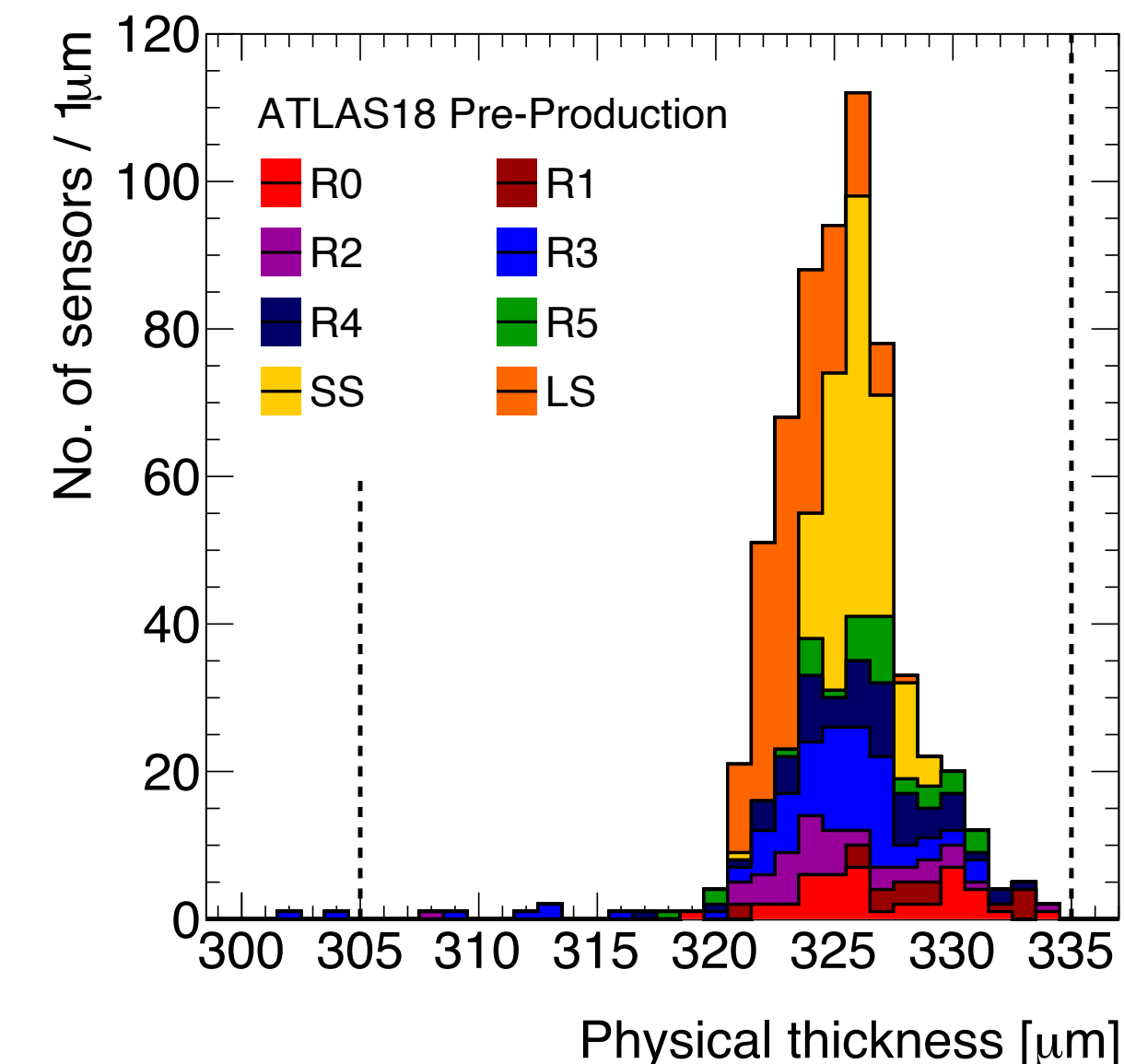
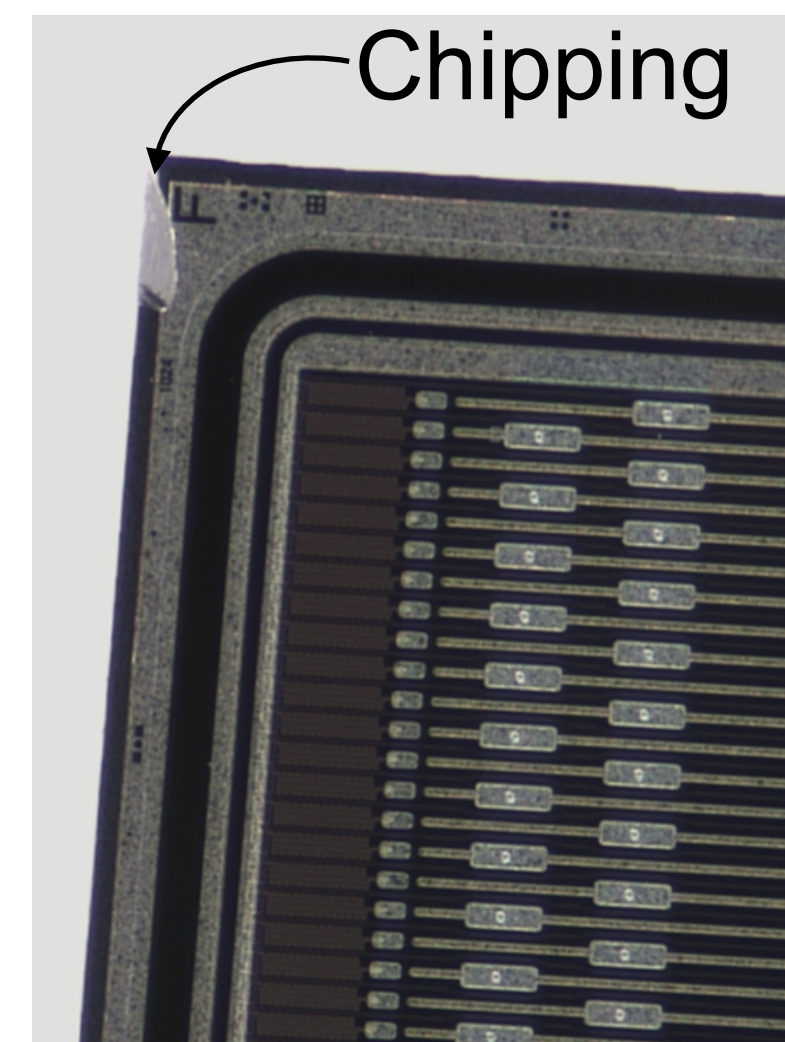
Pre-Production	all 8 types	HPK	1,041	9.2 m ²	completed
Production	all 8 types	HPK	20,800	190.3 m ²	ongoing

The ITk Strip Sensors - QA/QC

Extensive QA/QC is carried out in several institutes for either all sensors or sample of them:

- All Sensors
 - **Visual** inspection, planarity (<1% failures)
 - **IV** ($V_{bias} = 500\text{ V}$ & $I < 0.1\ \mu\text{A}/\text{cm}^2$) under dry conditions (3.5% failing)
- Subset of sensors:
 - **Thickness** measurement on **test sensors** with calipers ($320 \pm 15\ \mu\text{m}$)
 - **Long-term stability** (40h at 400-500 V, 2-5% of sensors)
 - **Full Strip Test**, probing each strip, measure currents and $R_{bias} = 1 - 2\ \text{M}\Omega$, $C_{coupling} > 20\ \text{pF}/\text{cm}$

[Poster on Humidity exposure by Vitaliy](#)



QC Test	Vis. Insp.	Metrology	Thickness	IV	CV	LTS	Stripstest
Yield (Fails)	99.6% (4)	100%	99.7% (2)	96.5% (36)	100%	99.3% (4)	99% (4)

Talks on QA/QC: [by Eric](#) & [by Christoph](#)

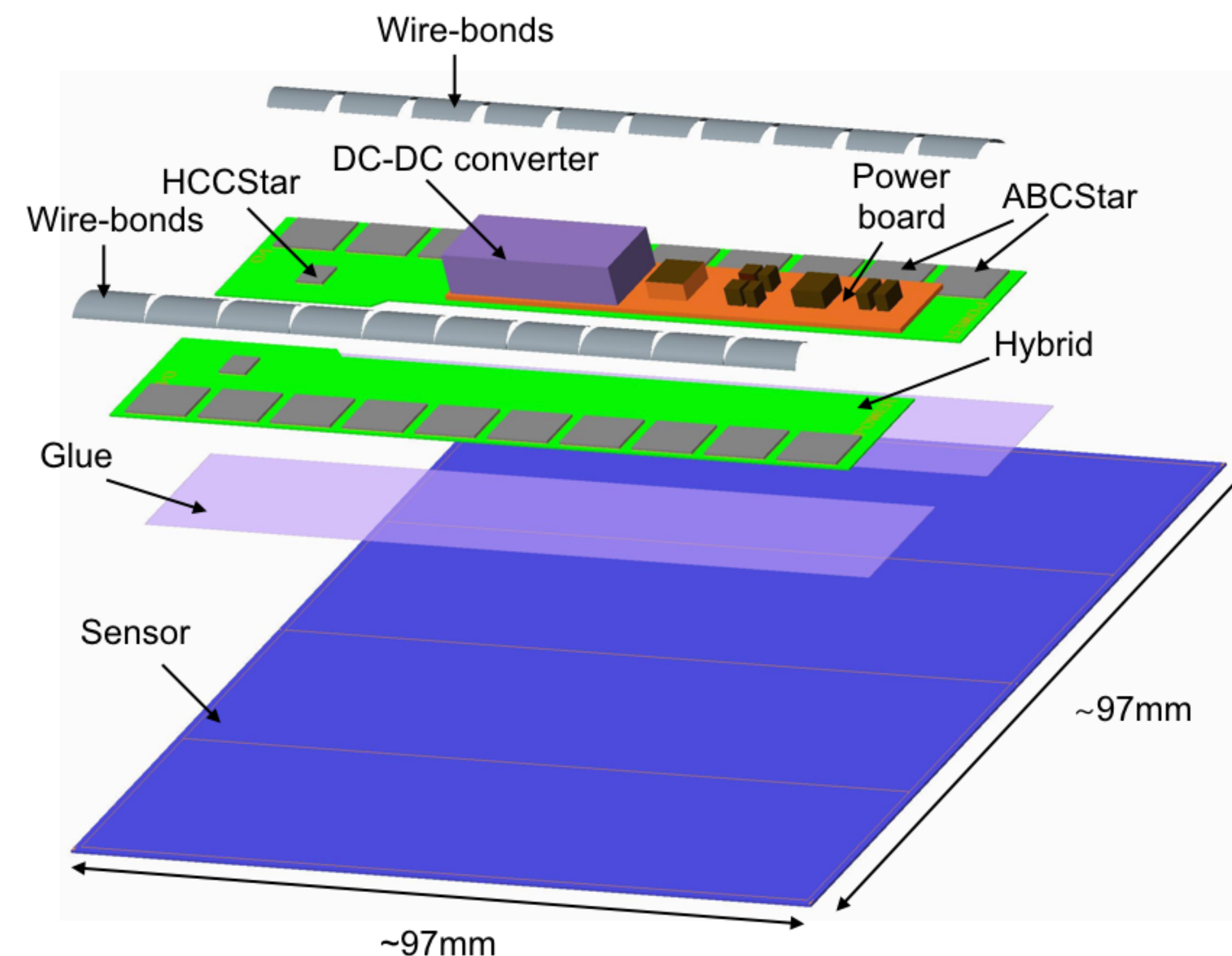
Posters on QA/QC [by Andrew](#) & [by Paul](#)

Talk on Sensor recovery [by Ezekiel](#)

The ITk main element: Module

The main detector element in ITk is the **module** which consists from:

- **Diced Sensors**
- **Hybrid** board (glued on the Sensor) consists of **ABCStar** custom frontends and **HCCStar** custom readout ASICs
 - * wire-bonded to the sensor
- **Power-board** (glued) which has **AMACStar** ASIC for controls, HV multiplexer, **DCDC** (linPOL12V, bPOL12V - CERN development)
 - * wire-bonded to Hybrids



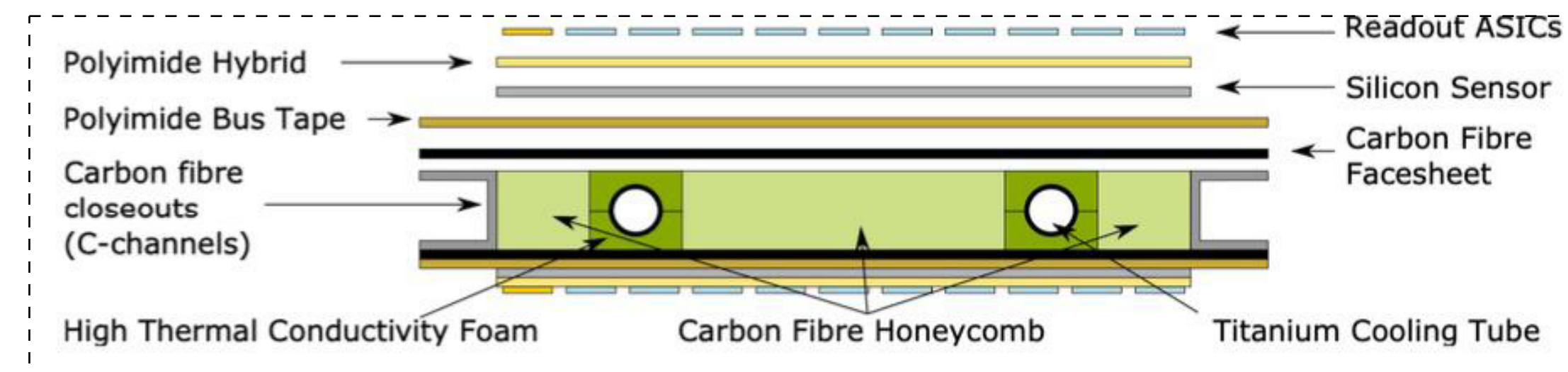
Short strip module
exploited view

[ATLAS-TDR-025](#)

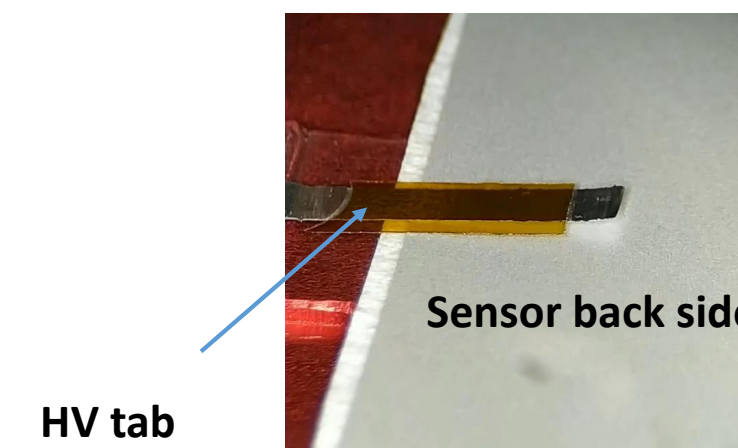
Core supports

- **Carbon-fibre structures** form the **support** for the modules and the EoS
- Copper on Polyimide (kapton) **bus-tapes** are used to route electrical connections (inc. power)
- **Titanium** pipes used for evaporative CO₂ cooling in highly thermal-conductive carbon-fibre honeycomb - operation at $\sim -35^{\circ}\text{C}$
- **Modules** are **glued** on either side of the core and **wire-bonded** to bus-tapes

Stave Cross section

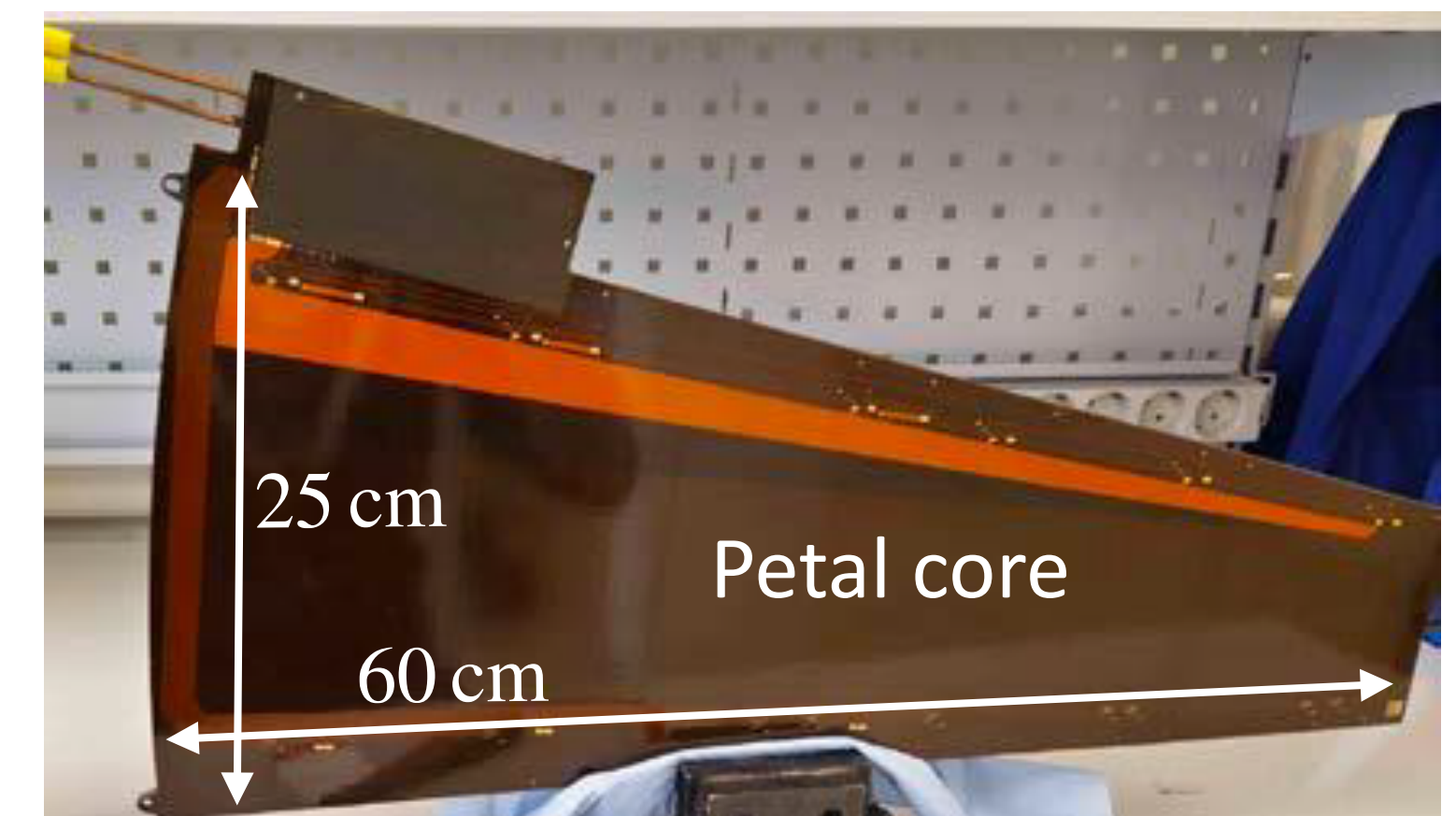
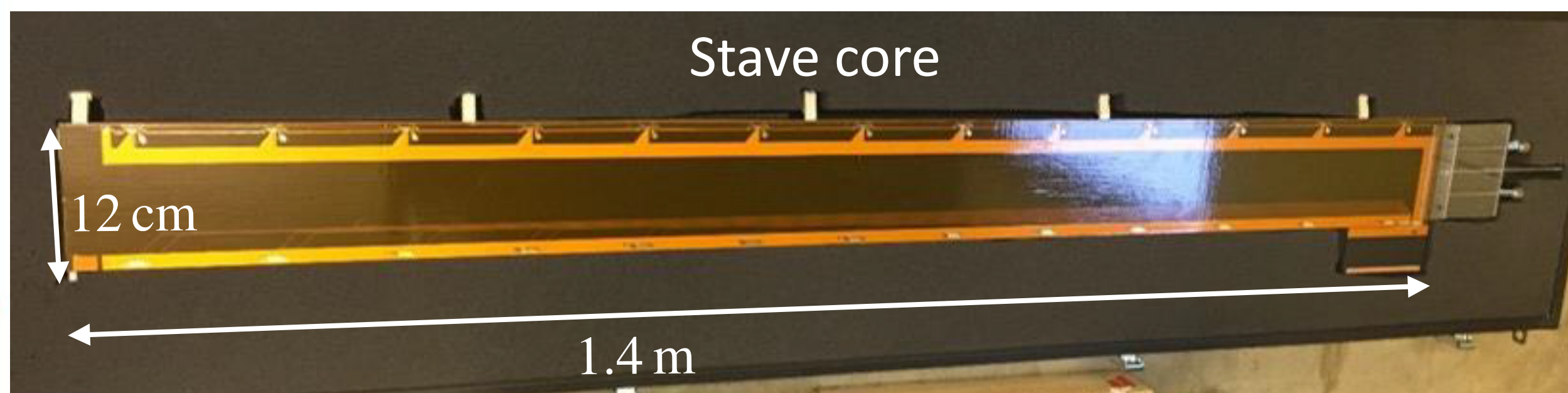
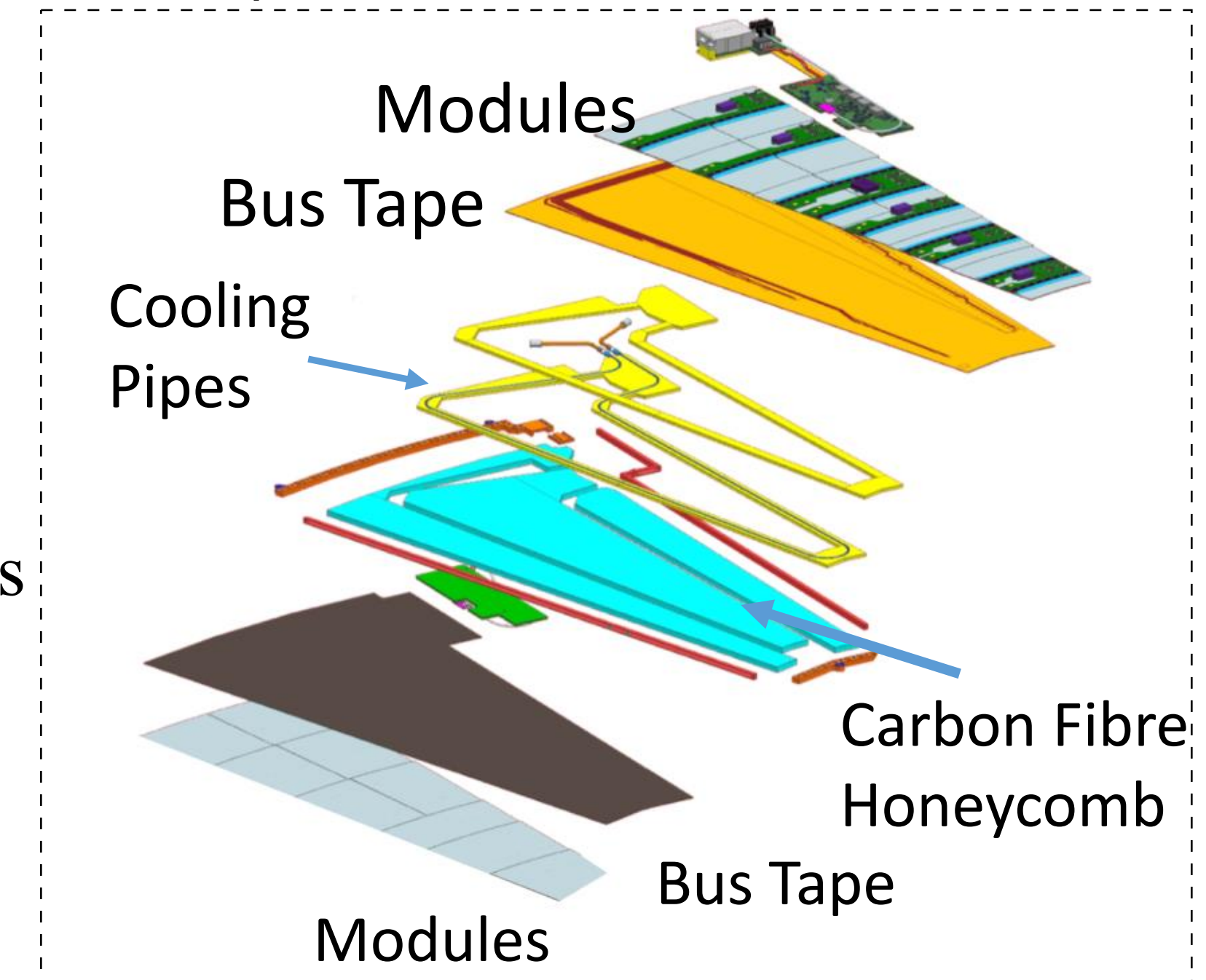


HV on sensor back plane by Tape Automated Bonding (TAB) bonding



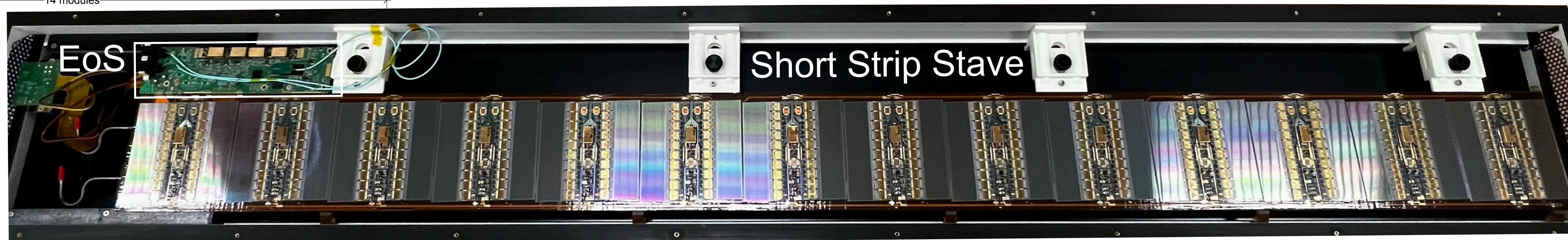
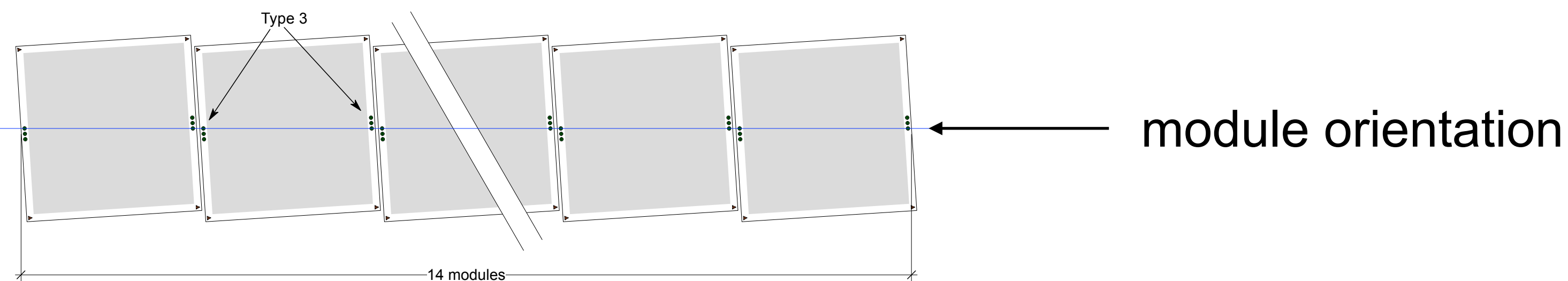
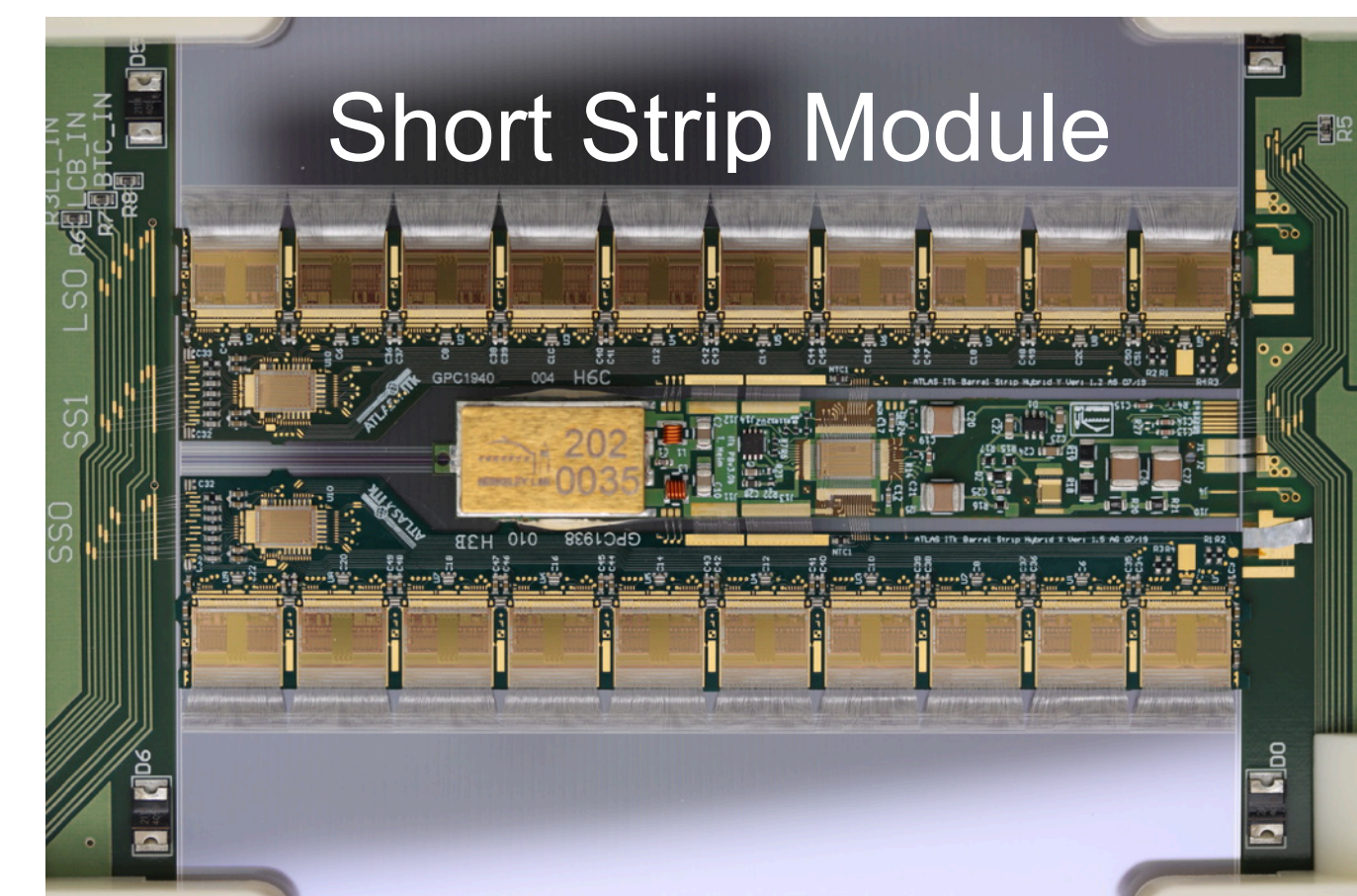
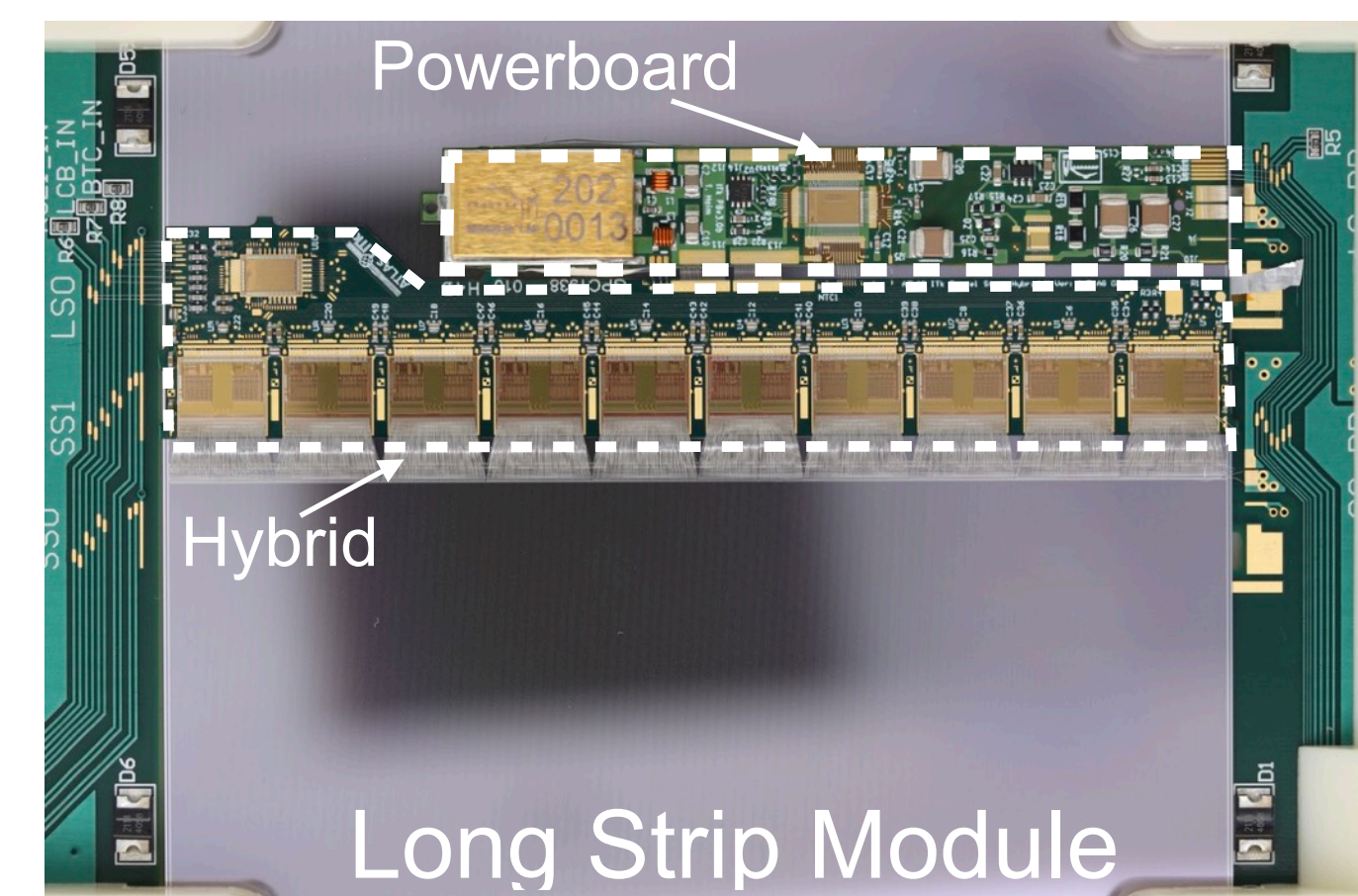
[Poster on local support structures by Sergio](#)

Petal exploded view



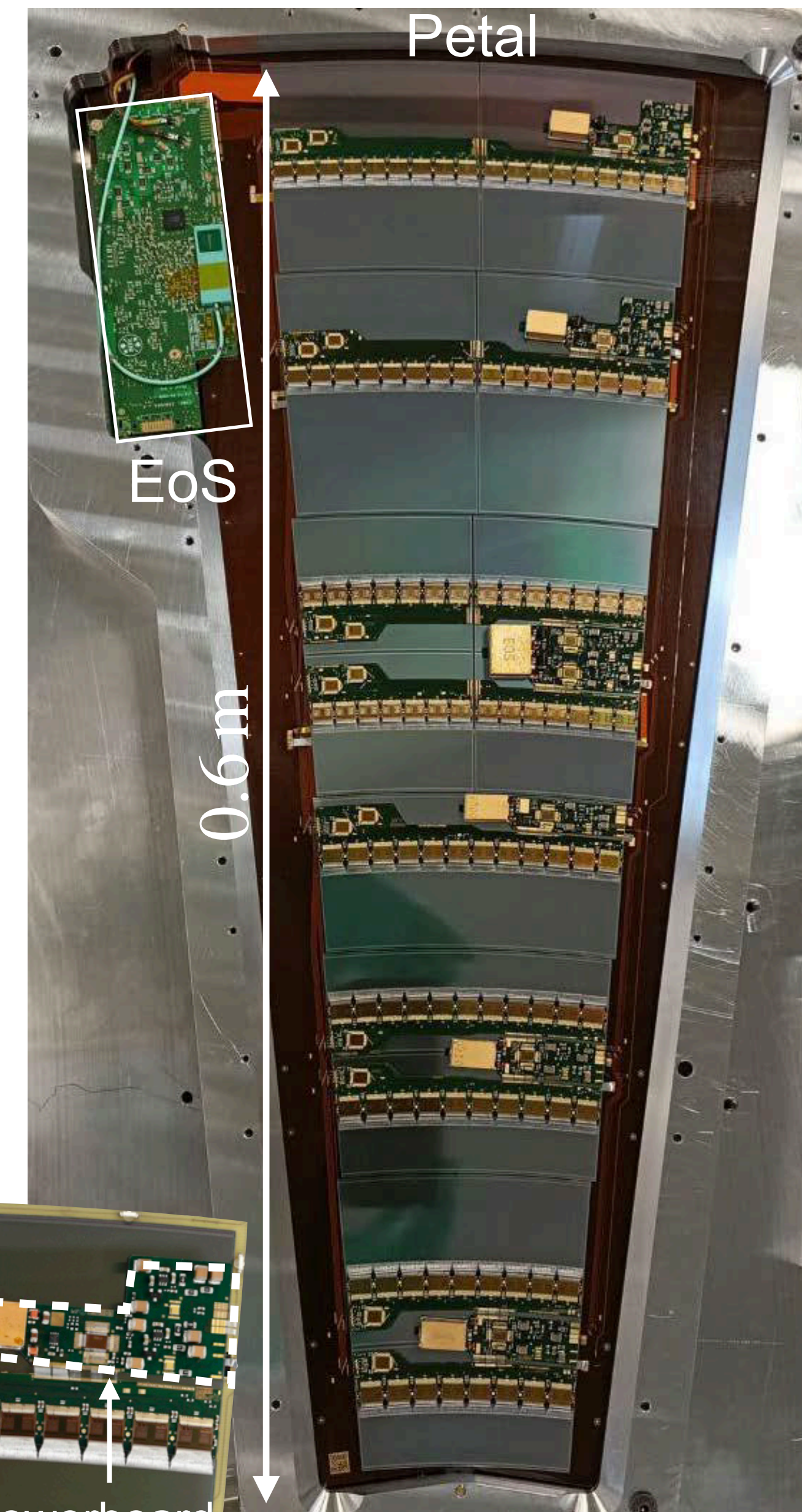
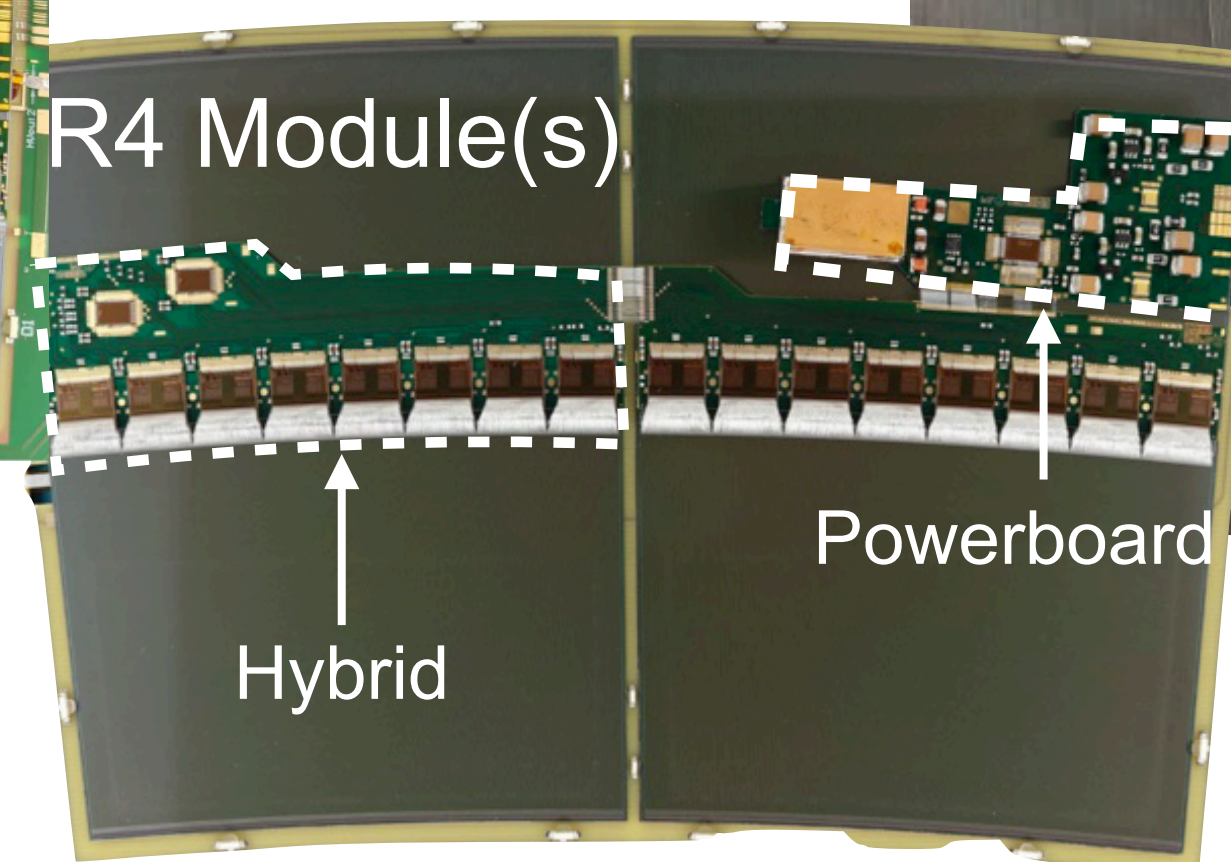
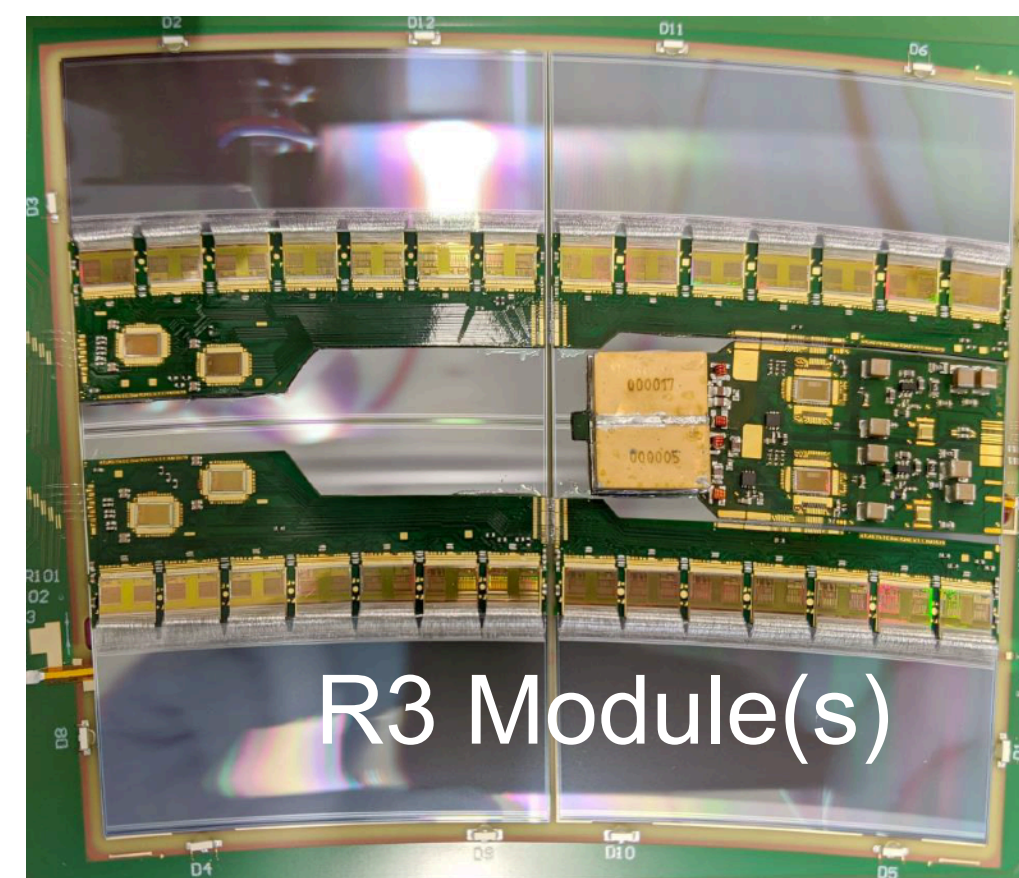
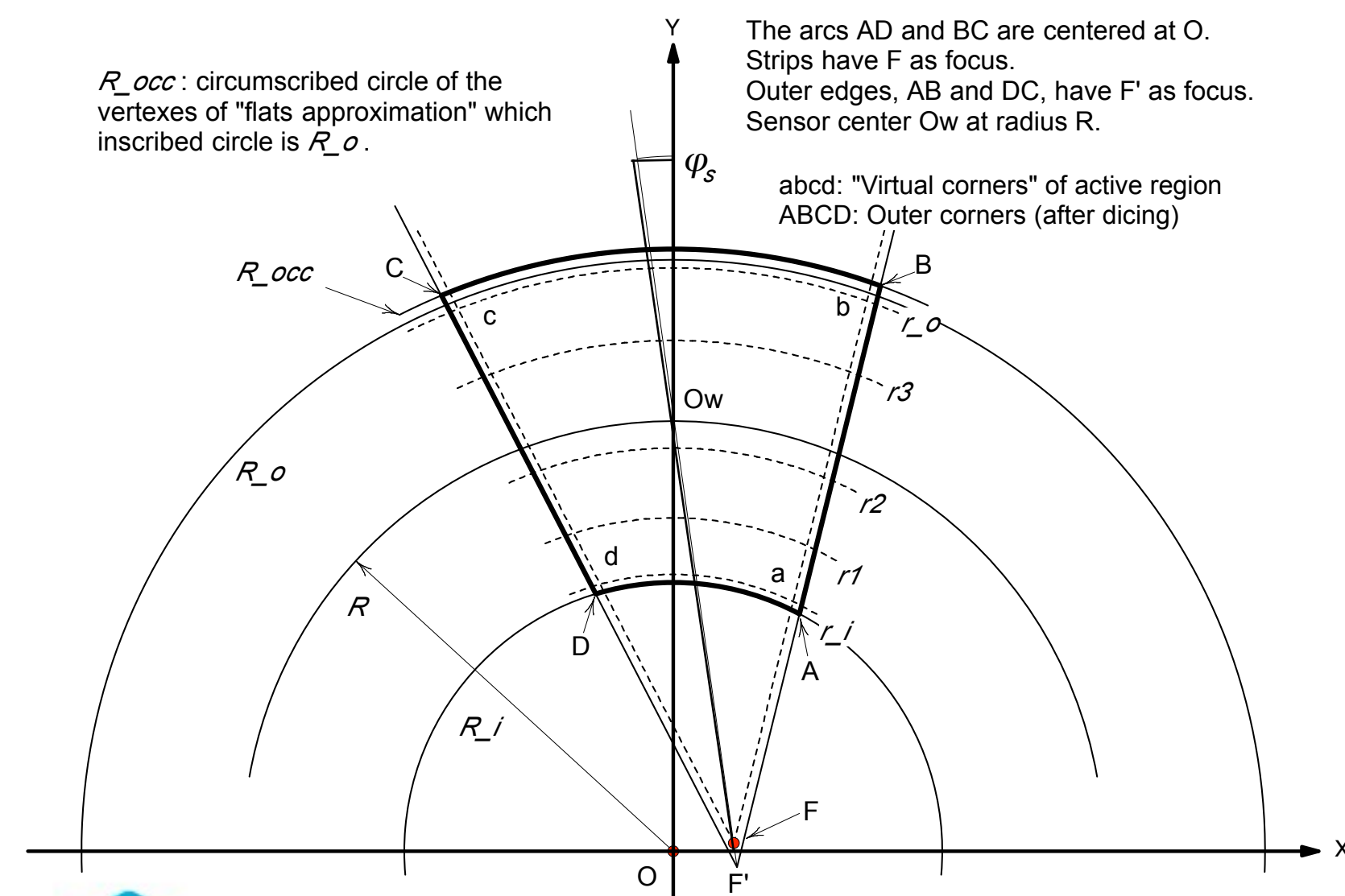
Barrel detectors: Staves

- **Modules** are loaded in structure to form **Staves**
- Staves consist of **28 modules** in total, **14 on either side of the stave core**
- Modules are **rotated** by 26 mrad to the stave axis to provide **stereo** information
- The End of Substructure (**EoS**) facilitates the communication through the CERN developed ASICs:
 - lpGBT (Low Power GigaBit Transceiver, 65 nm CMOS ASIC)
 - VTRx+: fibre transmitter - receiver (10 Gb/s - 2.5 Gb/s)



Endcap detectors: Petals

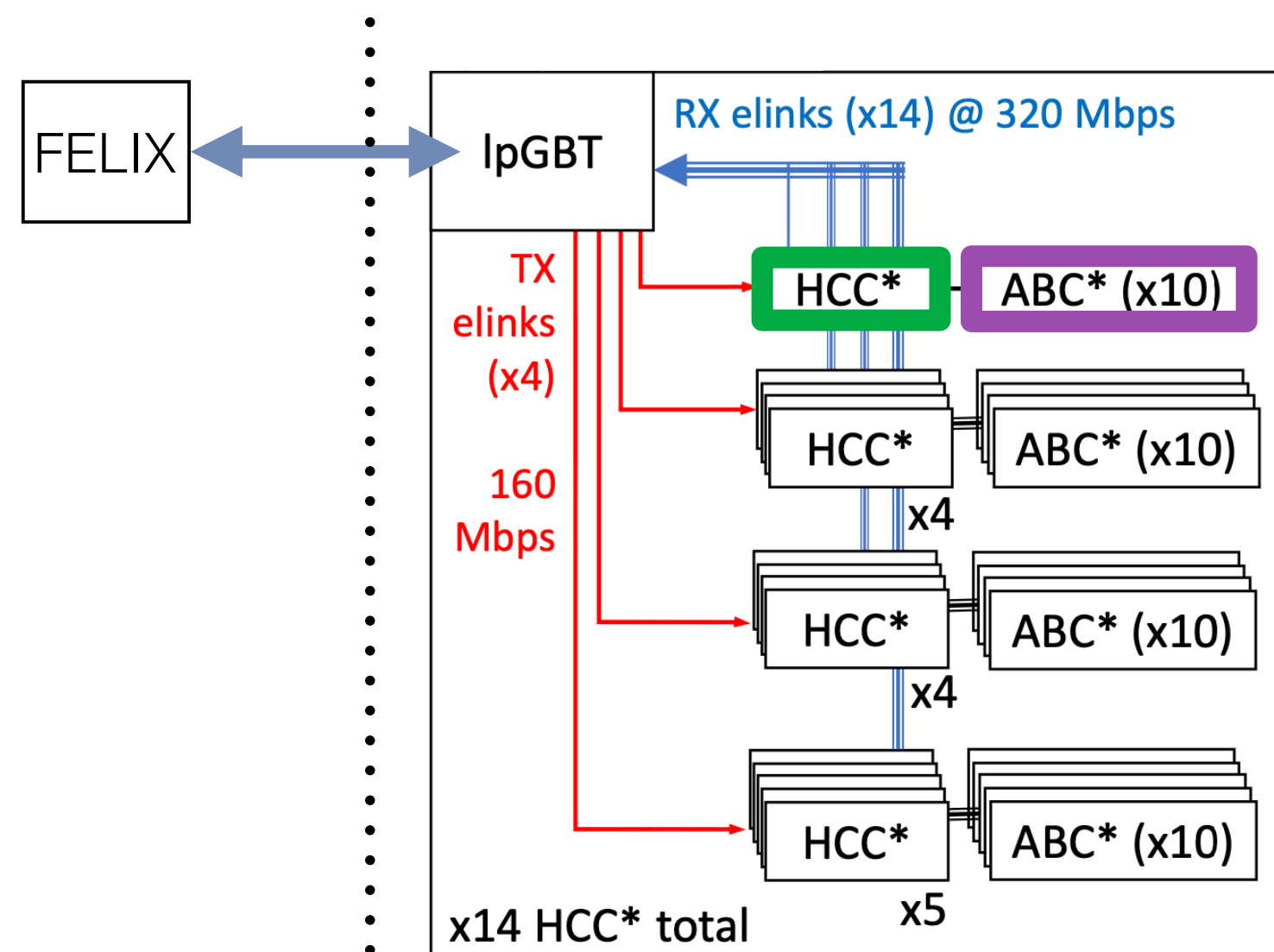
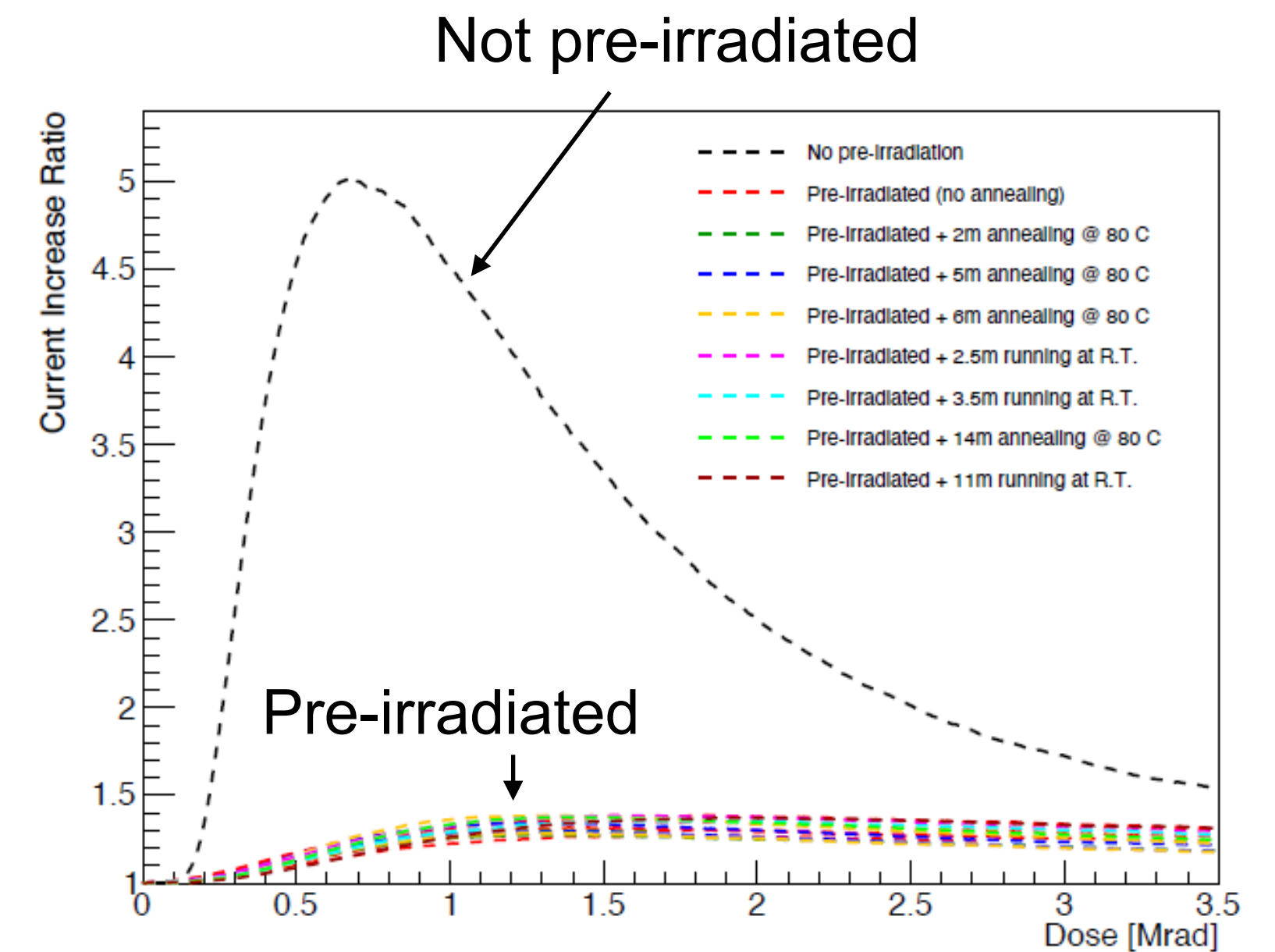
- In a similar way **Modules** loaded in **trapezoidal** structures form **Petals**
- Petals consist of 6 module variants - in total **18 modules**, **9 on either side** of the petal **core**
- Contrary to staves, petals feature strips which are **rotated** by an angle $\phi_s = 20 \text{ mrad}$ around the **center of the sensor** to provide stereo information
- **Petals** have more **variations of hybrids** due to the nature of their shape but all the ASICs and the EoS have **identical** to staves functionality



Electronics and Readout

- All three ASICs (ABCstar, HCCstar, AMACstar) are produced by Global Foundry (GF) in the 130 nm technology
- ASICs are pre-irradiated to 5 Mrad with ^{60}Co since their current consumption becomes more uniform afterwards
- Performance evaluated in test beam campaigns and extensive simulations,
- Readout performance (1MHz with link occupancy <90%, 6 μs latency) and developments studied at dedicated System test setups

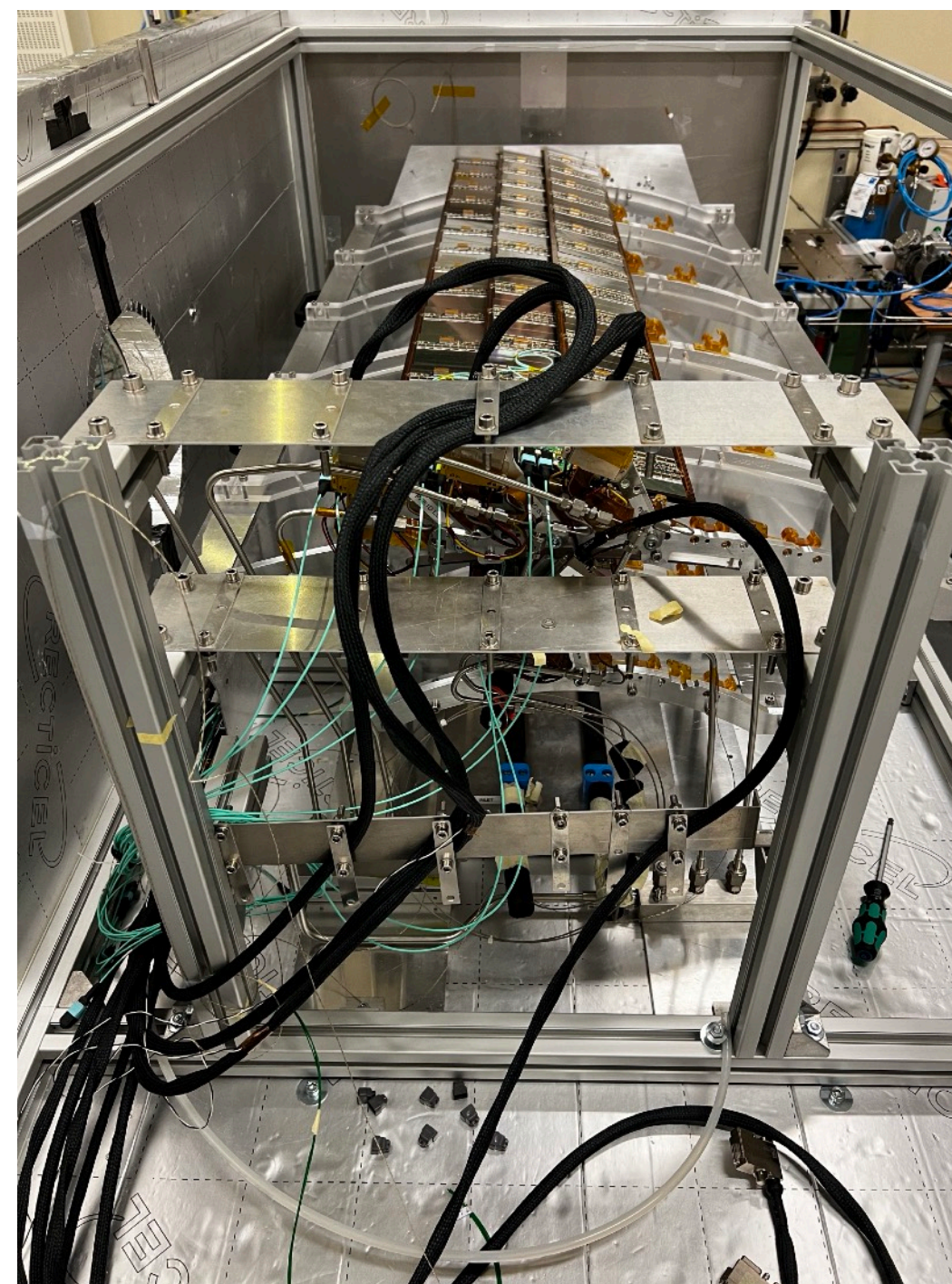
[Poster on SEU by Shaogang](#)



Off detector

On detector

Barrel System test at CERN



Endcap System test at DESY



[Talk on System tests by Jan](#)

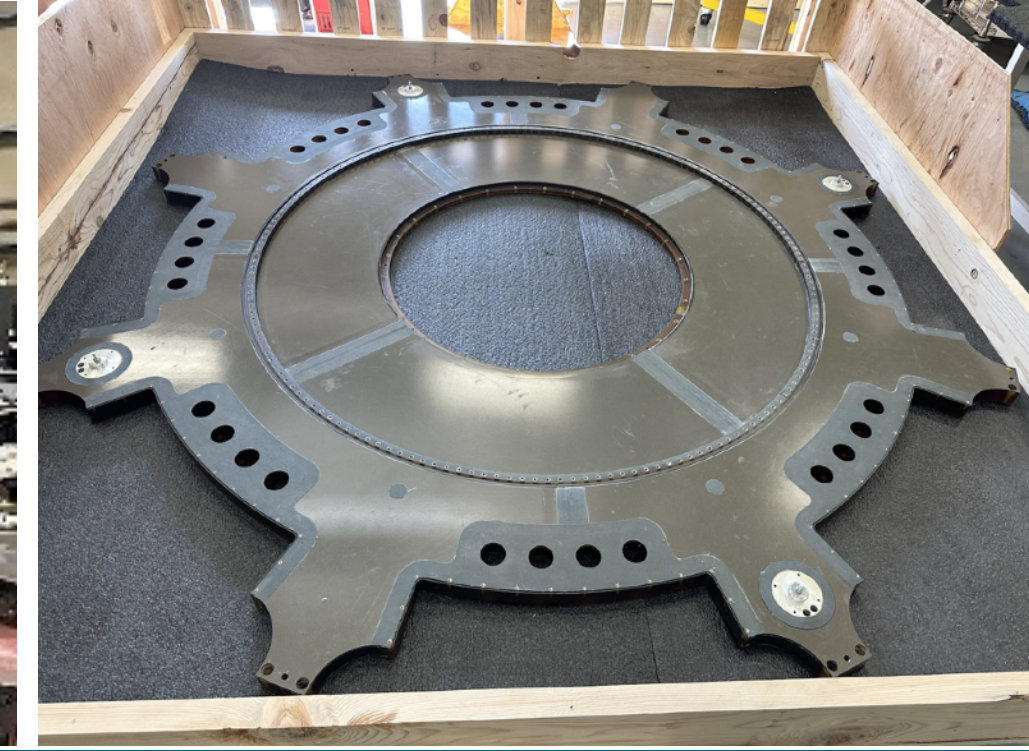
Structure Highlights

Global

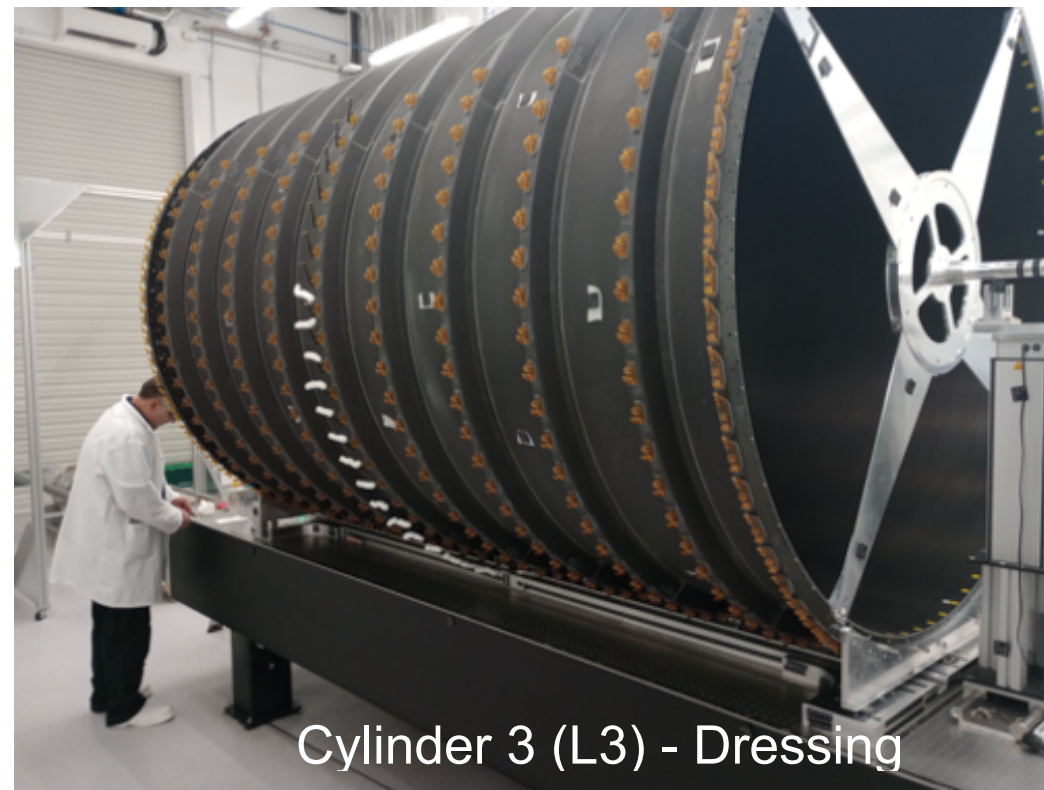
Global Structure :Outer Cylinder (OC)
Hosts the ITk



Bulkheads:
Close the volume on either end of OC



Barrel

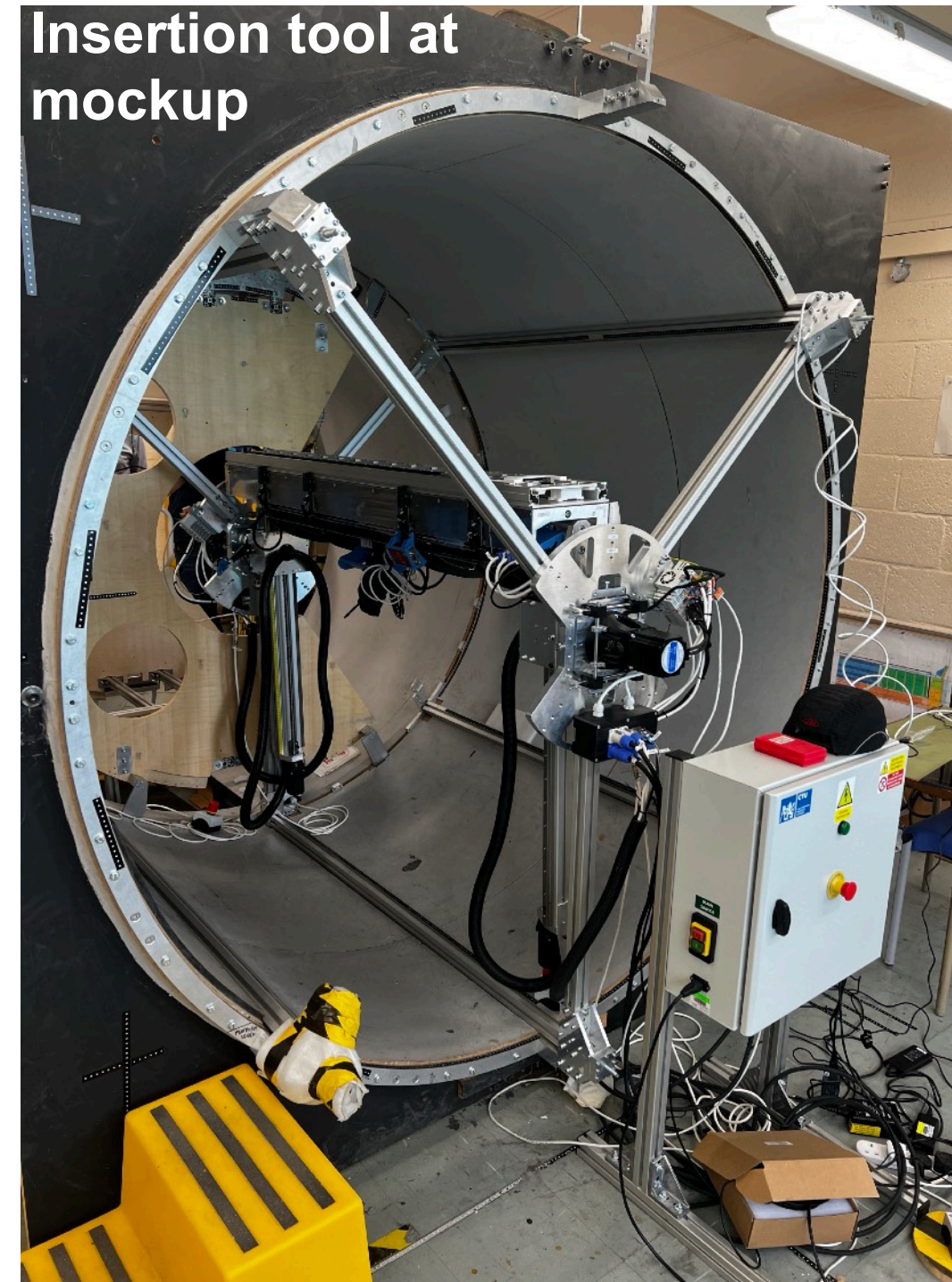


Cylinder 3 (L3) - Dressing

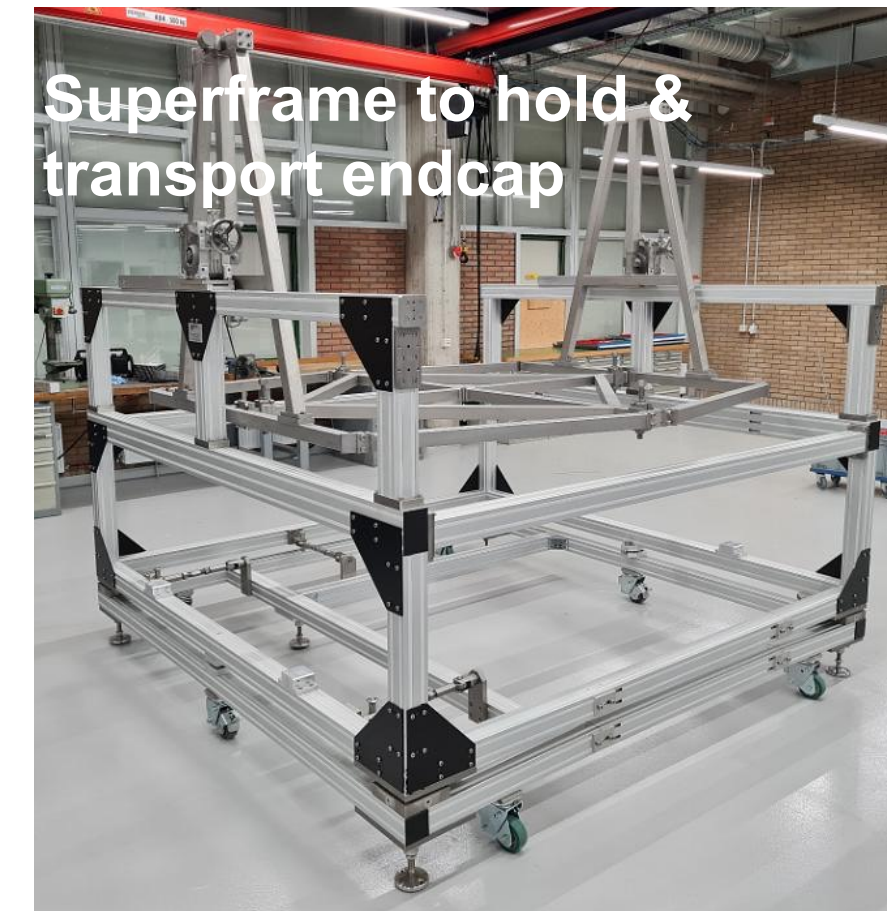


Cylinder 2 (L2) - Ready

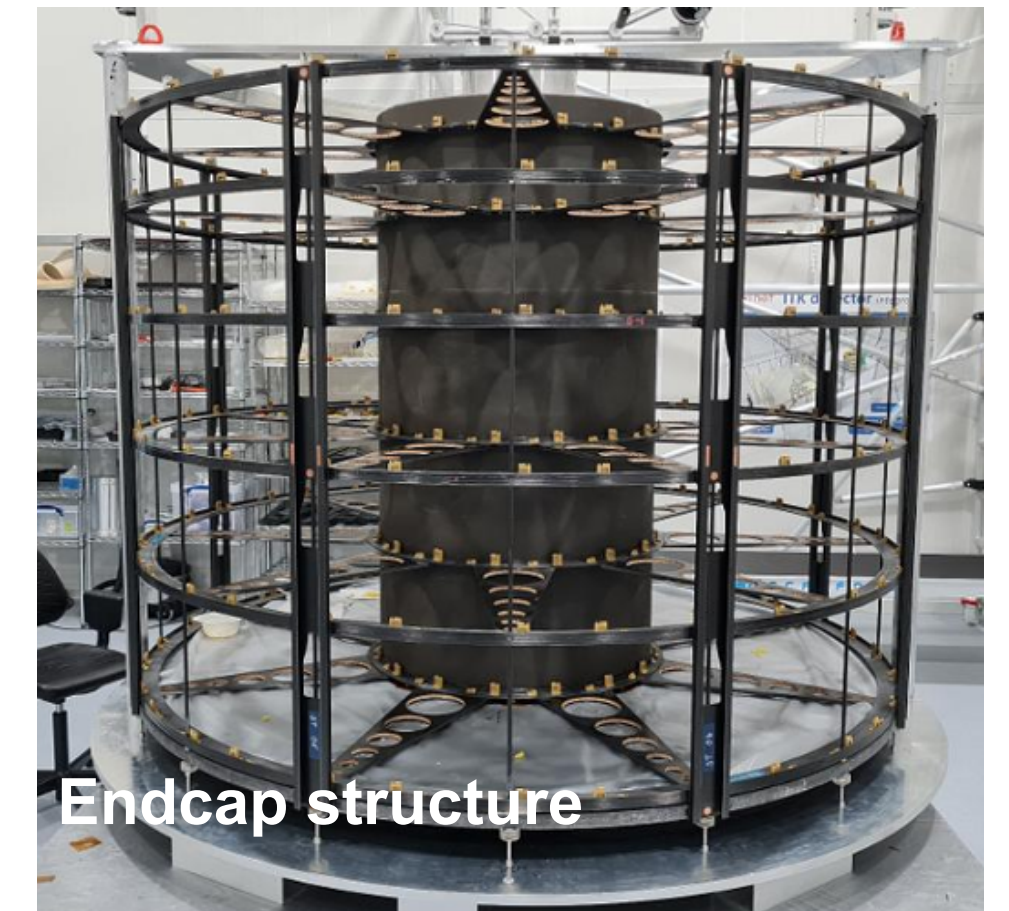
Insertion tool at mockup



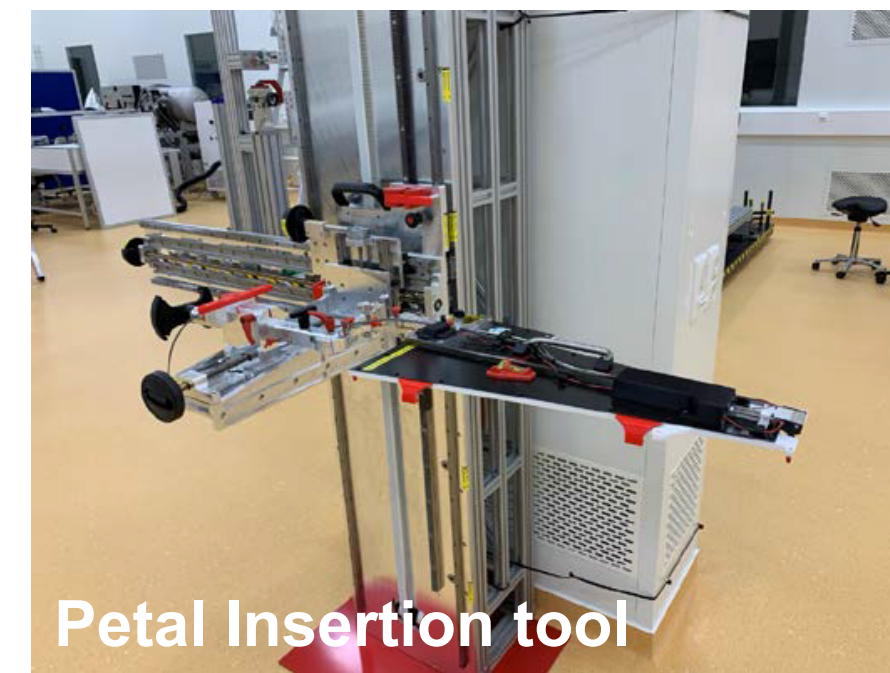
Endcap(s)



Superframe to hold & transport endcap



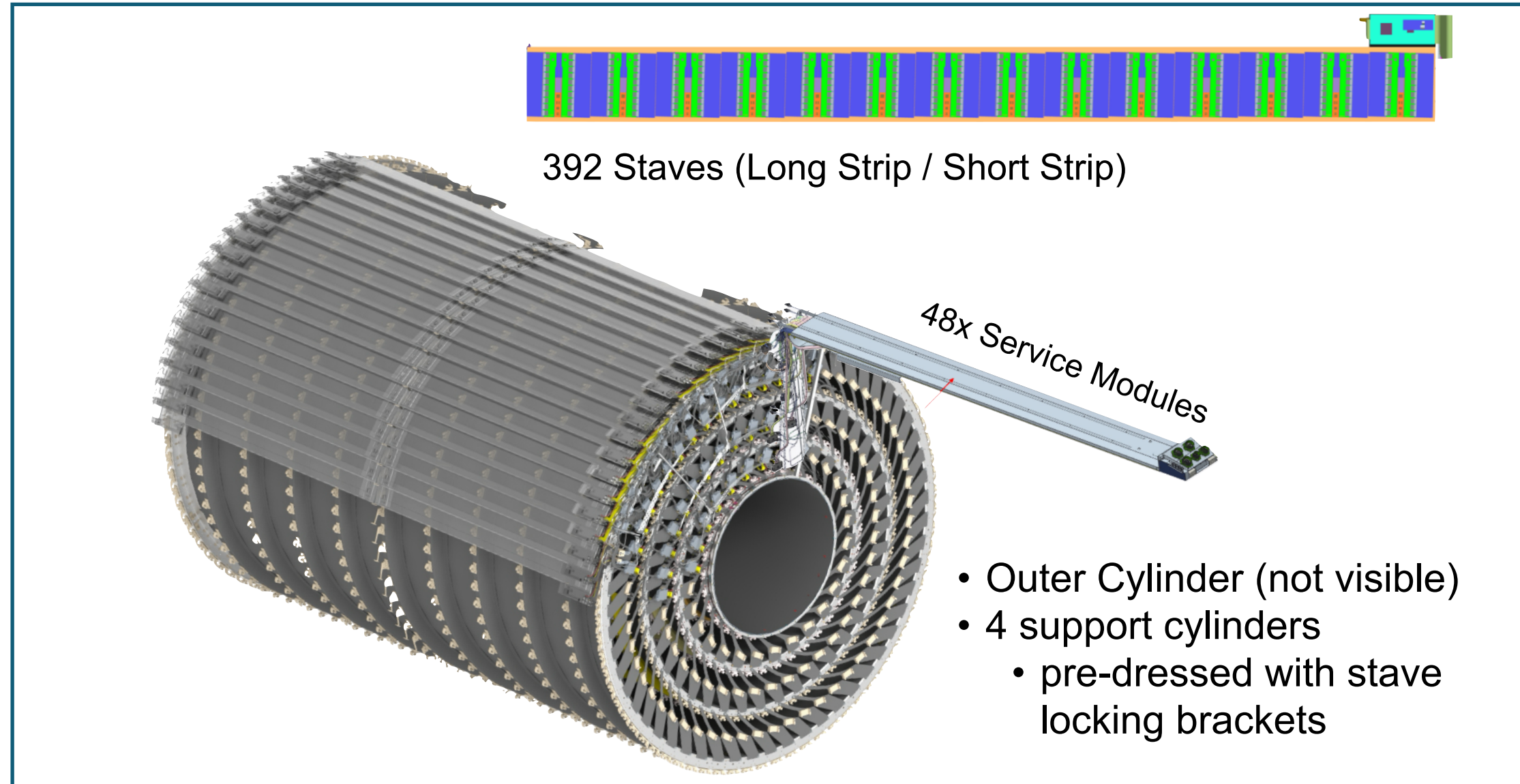
Endcap structure



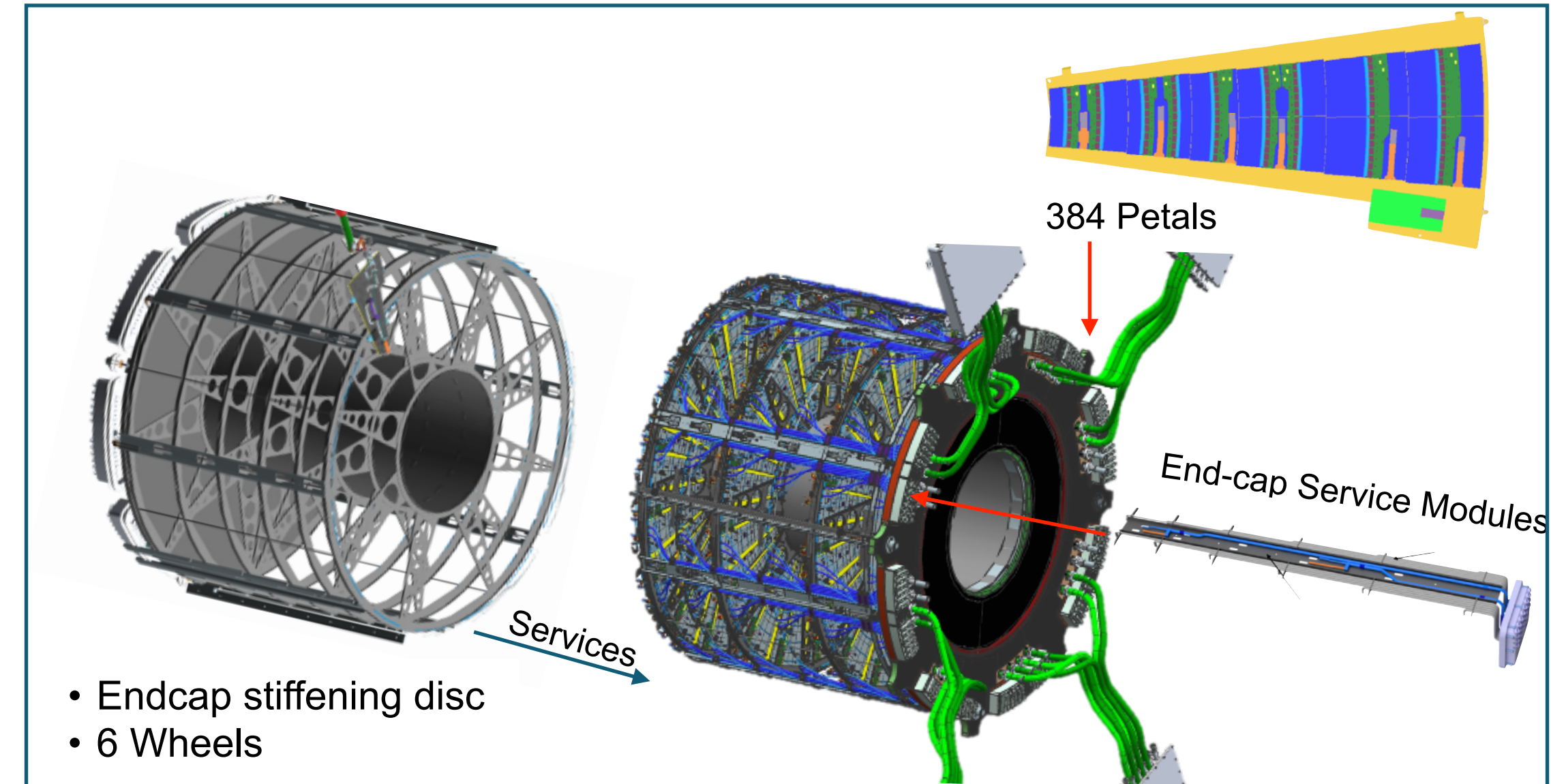
Petal Insertion tool

Integration

Barrel Integration at CERN

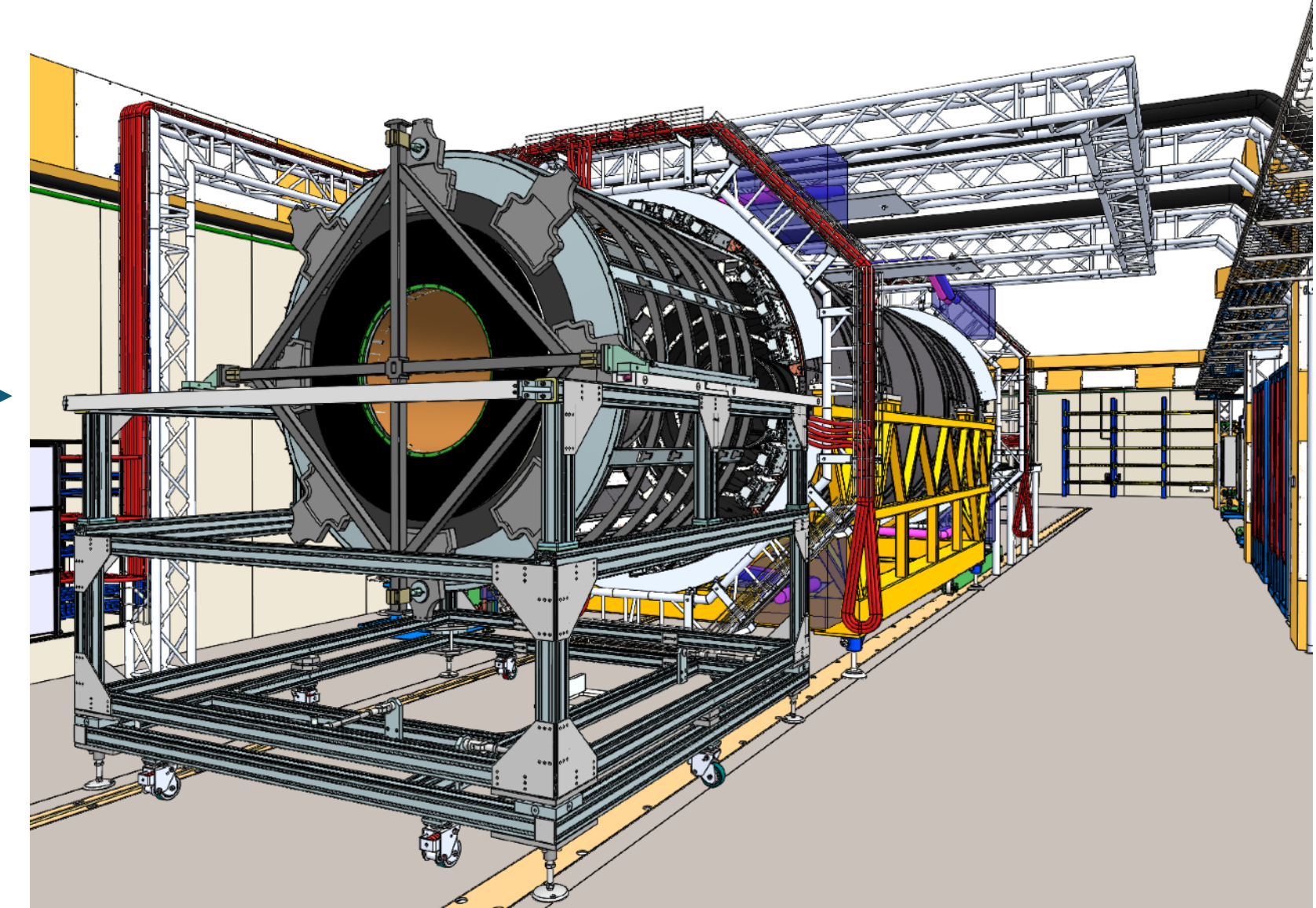


2x Endcap(s) - Integration at DESY, Nikhef



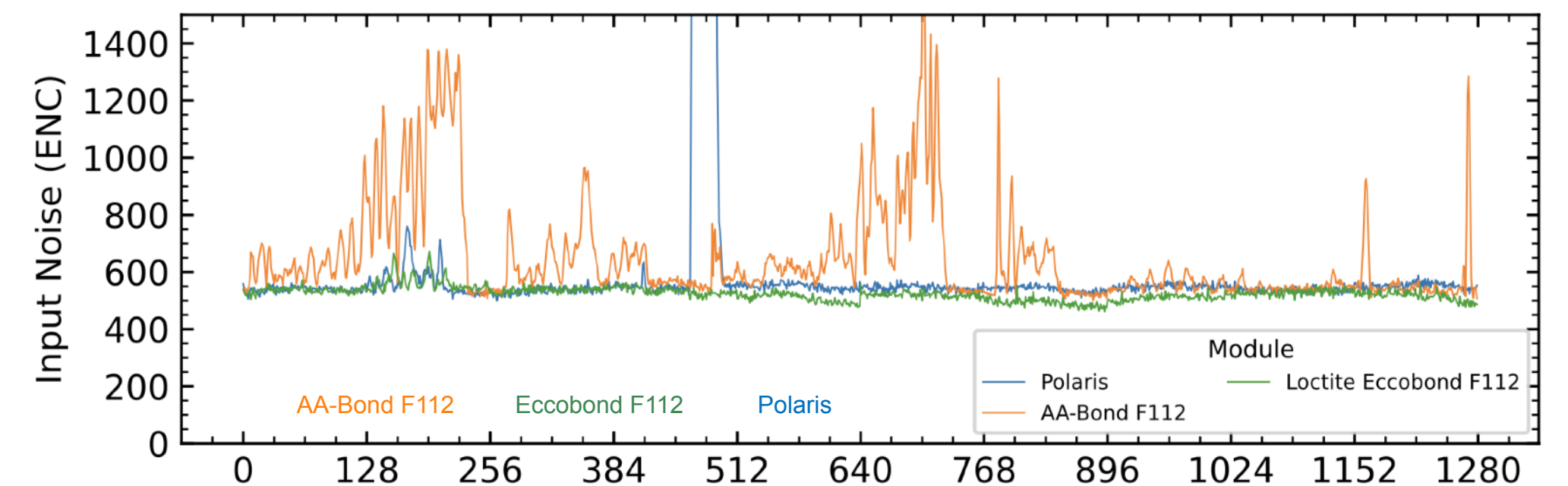
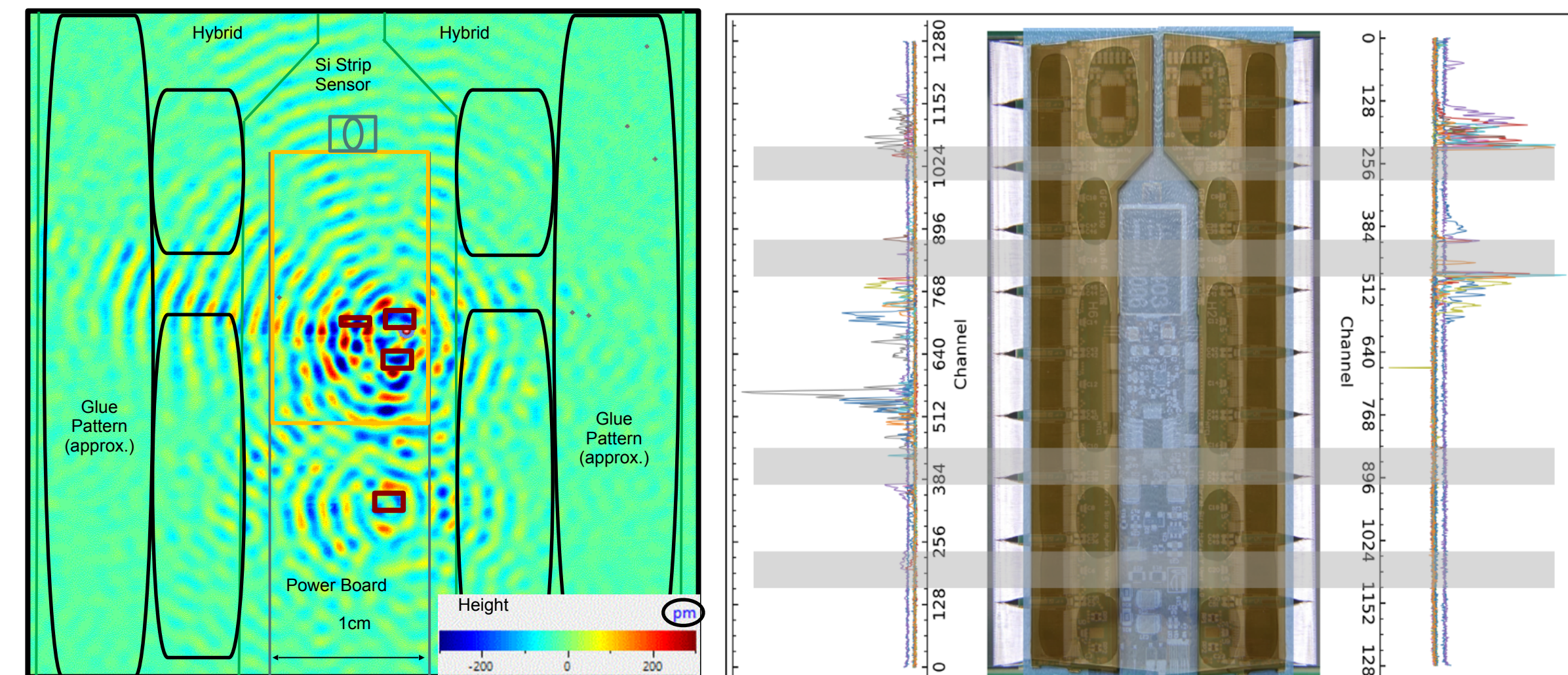
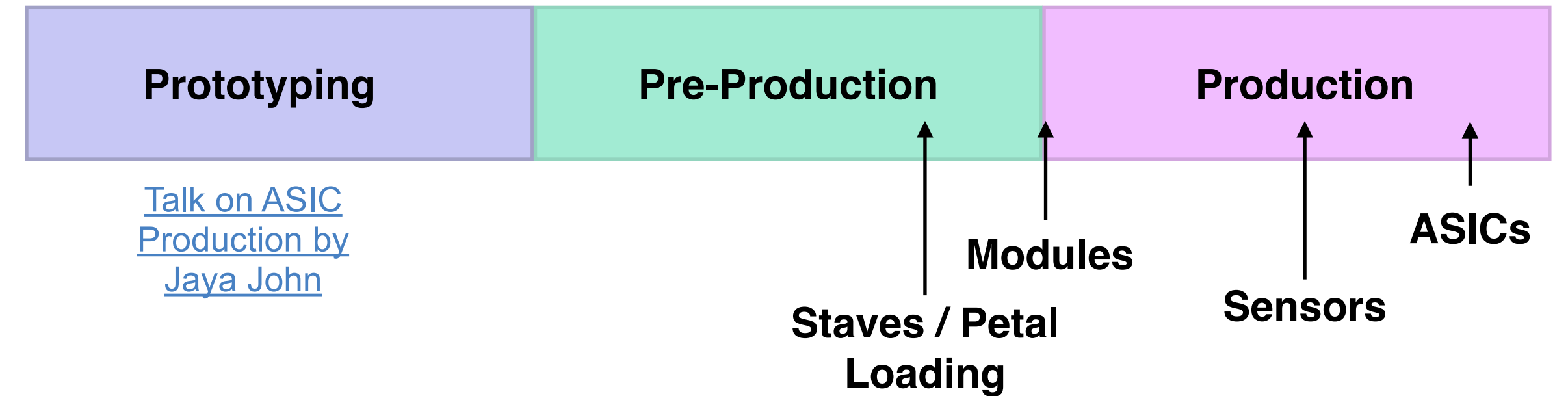
Complete endcaps to CERN

Complete ITk Strips detector



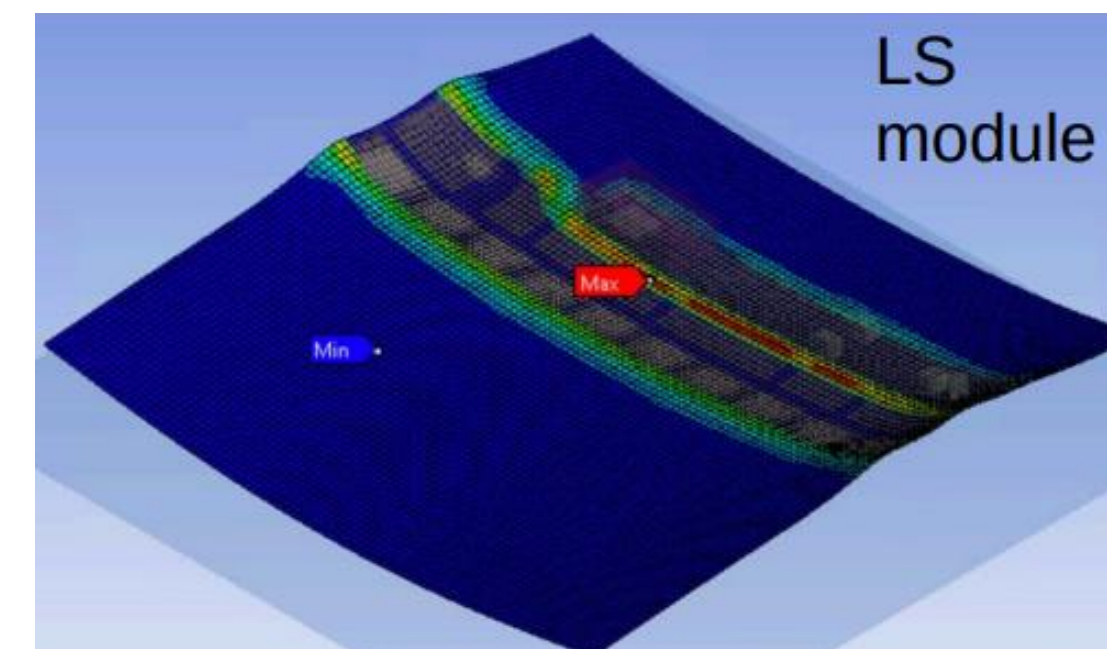
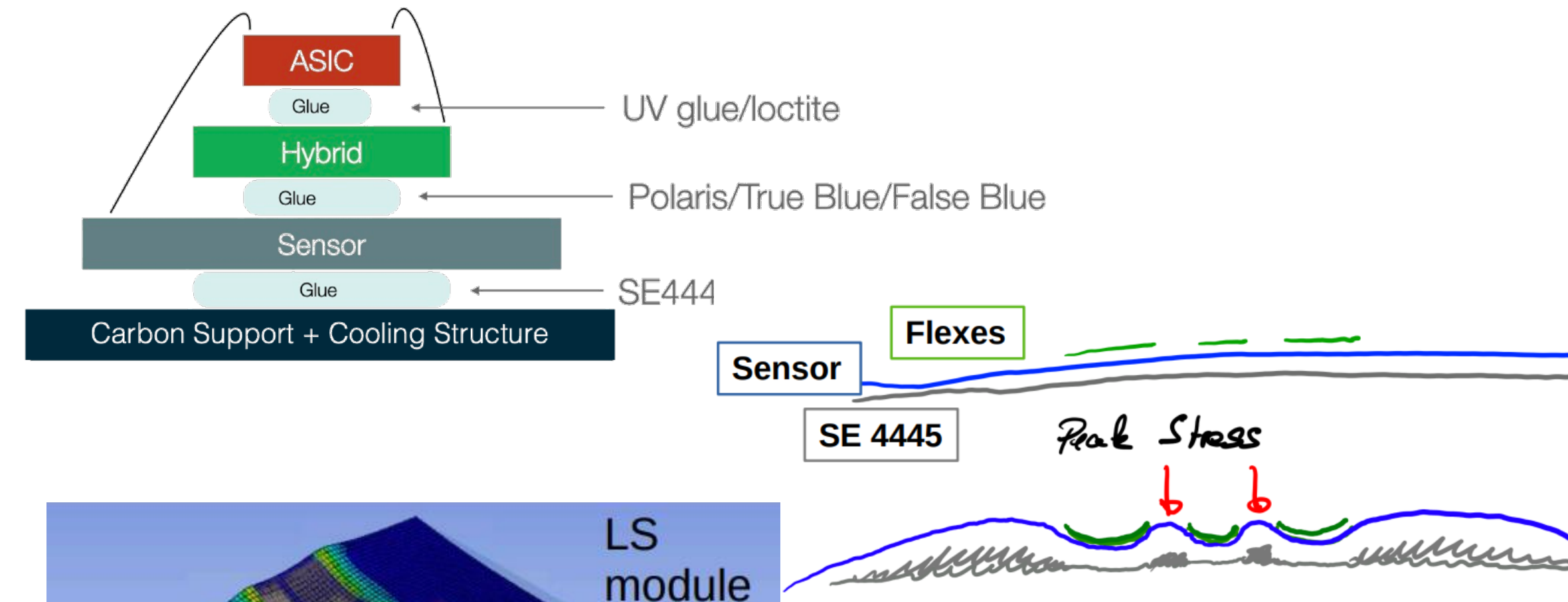
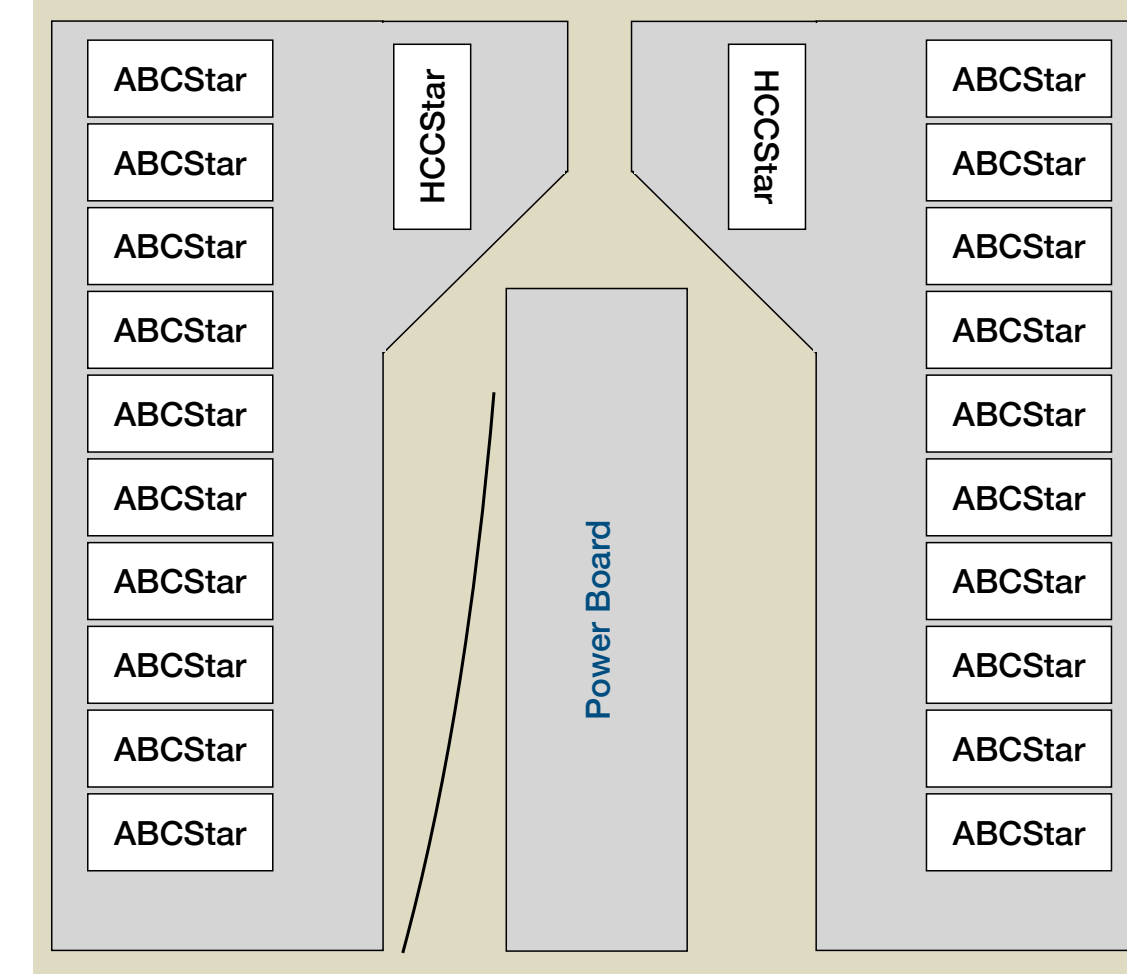
Current status - Towards production

- **Sensor** (>50% delivered) and **ASIC production** (>90% manufactured) running **smoothly**
- **Unfortunately** on May 2022 before modules enter production, a **technical issue** was discovered”
- **Excessive noise** once at “Cold” temperatures below -20°C a.k.a “**Cold Noise**”
- **Dedicated studies** tracked down to capacitors in the DCDC domain of the powerboard vibrating at 2 MHz and those **vibrations** traveling across the sensor and coupling back into the sensors
- By May 2023 a **mitigation** technique was put in place: changing the glue which minimises the noise



Current status - Sensor cracks

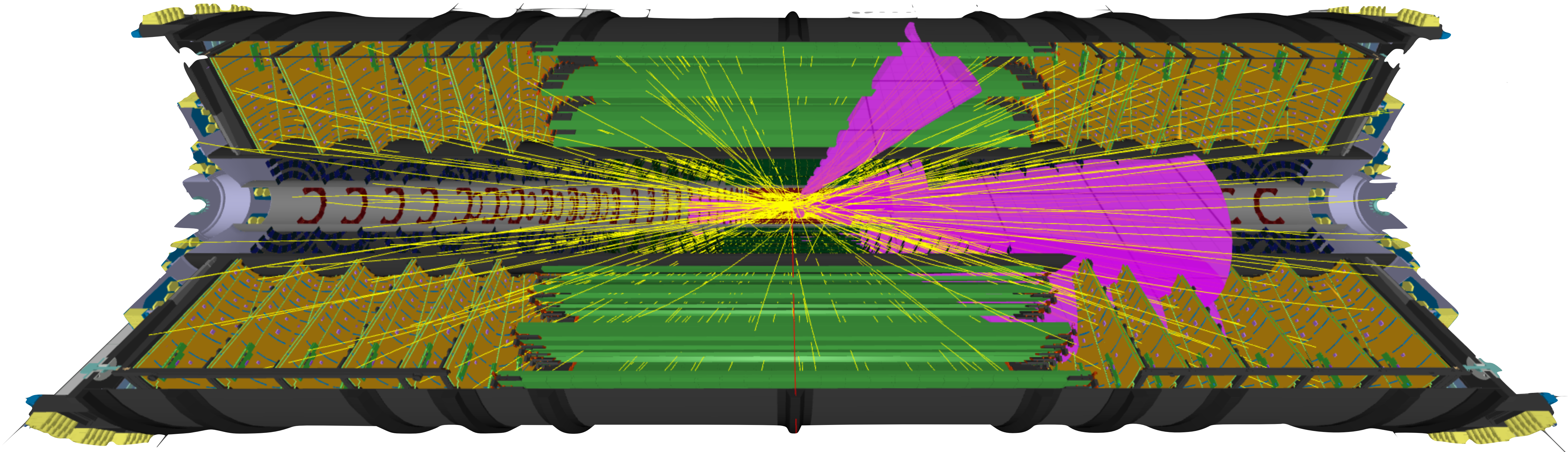
- Although a **mitigation** action has minimised the issue of “Cold Noise” **another technical challenge** was discovered
- In June 2023 we started to observe that we had **higher levels of high voltage breakdown** during **stave tests** than expected
- **Investigations** led to the discovery of **cracking** sensors
- **Studies are ongoing**, FEA simulations indicate the issue is the **CTE mismatch** between hybrids/ powerboards and sensors
 - Issue of different stiffness of the glue below and above the sensor
- Mitigation actions are explored and **studies are ongoing**



Summary

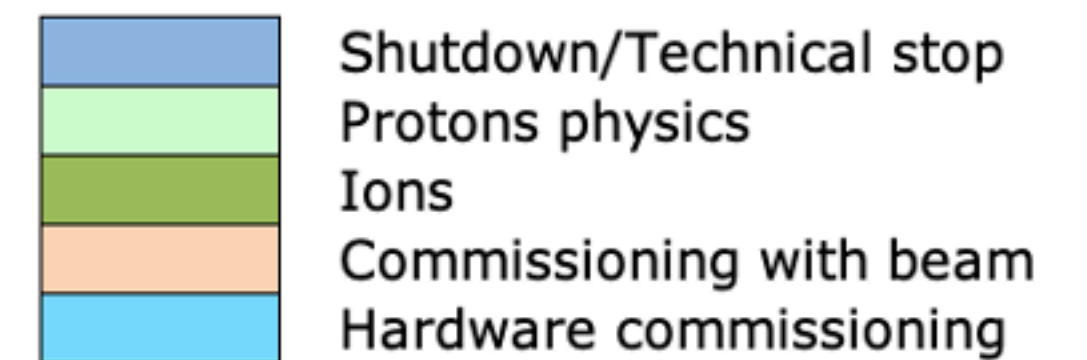
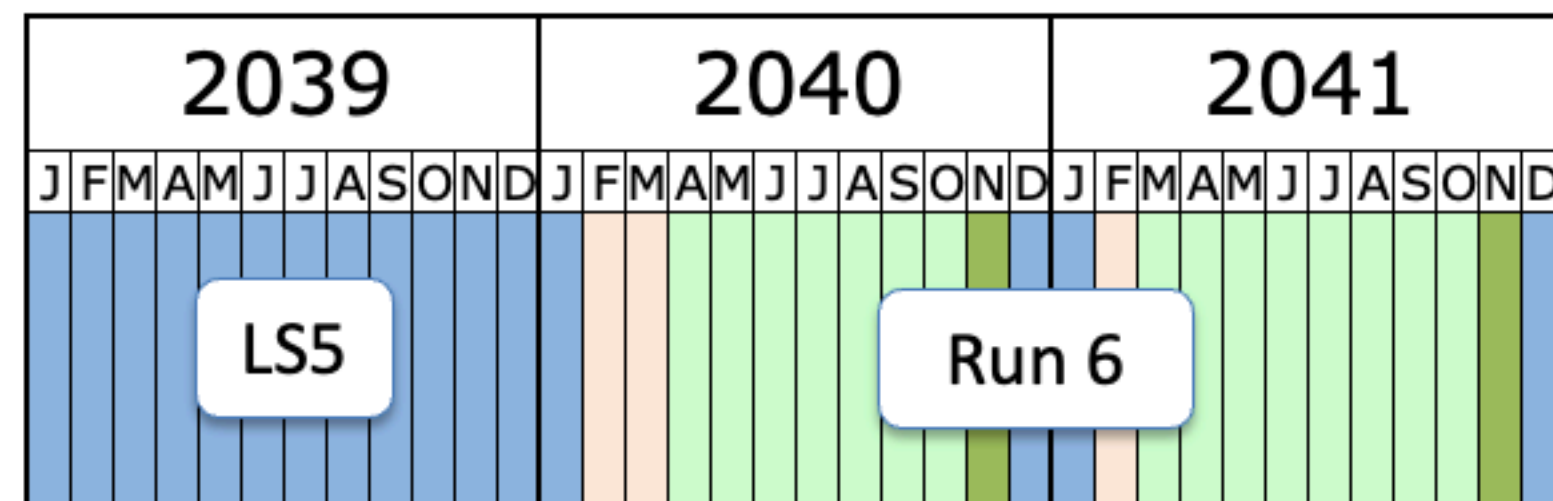
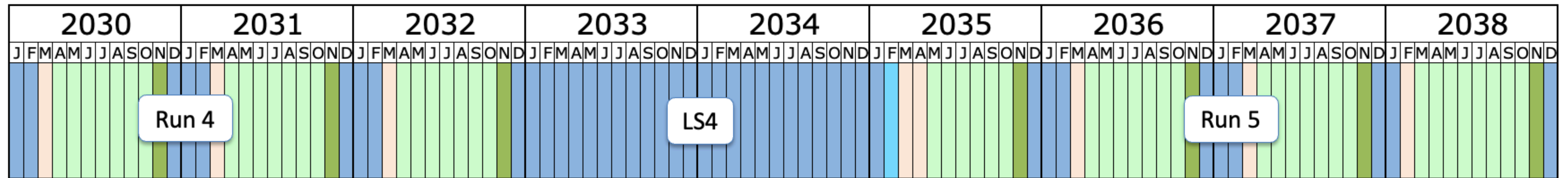
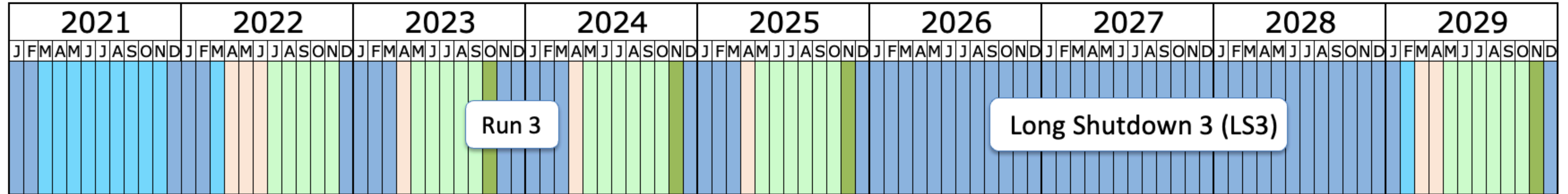
- In view of **HL-LHC**, the ATLAS experiment will **upgrade** its complete Inner Detector with an all silicon **Inner Tracker (ITk)**
- ITk is **expected to improve** the ATLAS performance operating under a harsh environment
- The **Strips detector** has been through many years of **design and R&D** with the **pre-production** smoothly ongoing in several areas
- **Major advancements** on the construction of **structures, services** and **preparation for integration**
- **Two major technical issues** have derailed the production schedule though:
 - The community is working hard to address and mitigate those issues such that production of Modules can be launched
 - Initial results from mitigation techniques are encouraging

Thanks !



Backup

LHC Long term schedule



Last update: April 2023

Numbers

Barrel Layer:	Radius [mm]	# of staves	# of modules	# of hybrids	# of of ABCStar	# of channels	Area [m ²]
L0	405	28	784	1568	15680	4.01M	7.49
L1	562	40	1120	2240	22400	5.73M	10.7
L2	762	56	1568	1568	15680	4.01M	14.98
L3	1000	72	2016	2016	20160	5.16M	19.26
Total half barrel		196	5488	7392	73920	18.92M	52.43
Total barrel		392	10976	14784	147840	37.85M	104.86
End-cap Disk:	z-pos. [mm]	# of petals	# of modules	# of hybrids	# of of ABCStar	# of channels	Area [m ²]
D0	1512	32	576	832	6336	1.62M	5.03
D1	1702	32	576	832	6336	1.62M	5.03
D2	1952	32	576	832	6336	1.62M	5.03
D3	2252	32	576	832	6336	1.62M	5.03
D4	2602	32	576	832	6336	1.62M	5.03
D5	3000	32	576	832	6336	1.62M	5.03
Total one EC		192	3456	4992	43008	11.01M	30.2
Total ECs		384	6912	9984	86016	22.02M	60.4
Total		776	17888	24768	233856	59.87M	165.25

Electrical properties common to all types of sensors

Parameters	Initial condition (*1)	Post-irradiation (*2)
Wafer:		
Material	p-type Silicon, float-zone (FZ)	--
Crystal orientation	<100>	--
Resistivity	>3.5 kΩcm	--
Oxygen concentration	1.5x10 ¹⁶ to 6.5x10 ¹⁷ (atoms/cm ³)	--
Active thickness (tolerance)	>270 μm	--
Sensor:		
Full depletion voltage (V_{fd})	<350 V	--
Breakdown voltage (V_{bd})	>500 V	>500 V or $V_{fd}+50$ V
Maximum operating voltage	500 V (at sensor)	←
Leakage current	<0.1 μA/cm ² at 500 V, RH<10%	<0.1 mA/cm ² ←
Leakage current stability	<15% at 500 V, RH<10%, 24 hours, after temperature correction (*3)	←
Bad strips	≤8 consecutive, <1% per segment	←
Collected charge (MPV(*4))	>6350 electrons, at 500 V	←
Strip:		
Resistance of n-implant strip	<50 kΩ/cm	←
Resistance of AC-metal strip	<30 Ω/cm	←
AC coupling capacitance (C_{AC})	>20 pF/cm, at 1 kHz	←
Polysilicon bias resistor (R_b)	1.5 ± 0.5 MΩ	1.8 ± 0.5 MΩ
Inter-strip resistance (R_{int})	>10× R_b , at 300 V	← at 400 V
Inter-strip capacitance (C_{int})	<1 pF/cm (*5), at 300 V to its nearest neighbors on both sides, at 100 kHz or 1 MHz (main sensor or mini sensor, respectively)	← at 400 V

Radiation Safety Factors

Layer	Radius [mm]	Maximal Fluence [n_{eq}/cm^2]	Maximal Dose [MRad]
Strips			
Long Strips	762	3.8×10^{14}	9.8
Short Strips	405	7.2×10^{14}	32.5
End-cap	385	1.2×10^{15}	50.4
Pixels			
Layer 0	39	1.87×10^{16}	1268
Layer 1	75	0.59×10^{16}	549
Layer 2	155	0.22×10^{16}	129
Layer 3	213	0.15×10^{16}	87
Layer 4	271	0.11×10^{16}	53
End-cap	80	0.62×10^{16}	477

[TDR of ITk Strips](#)

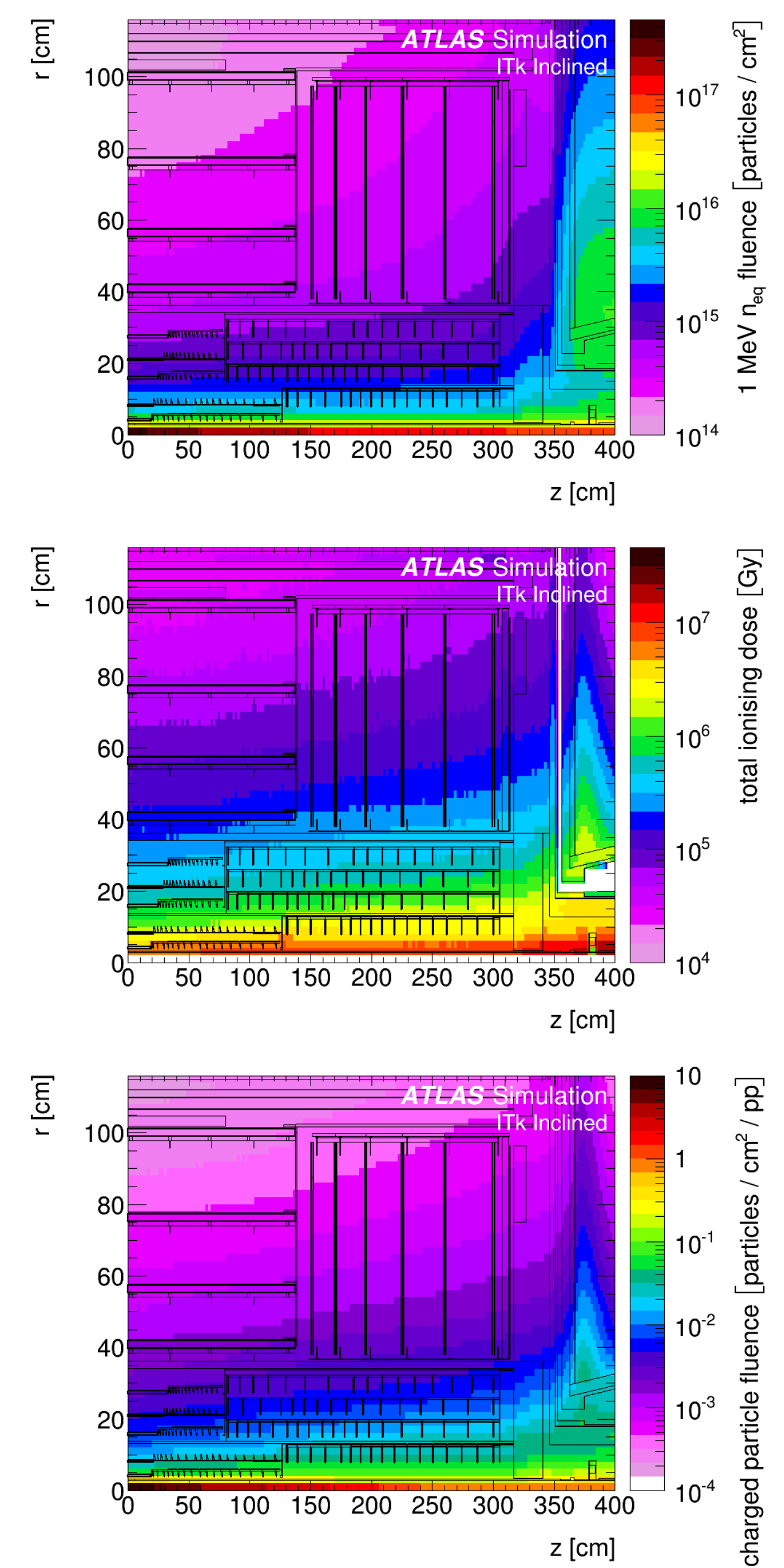
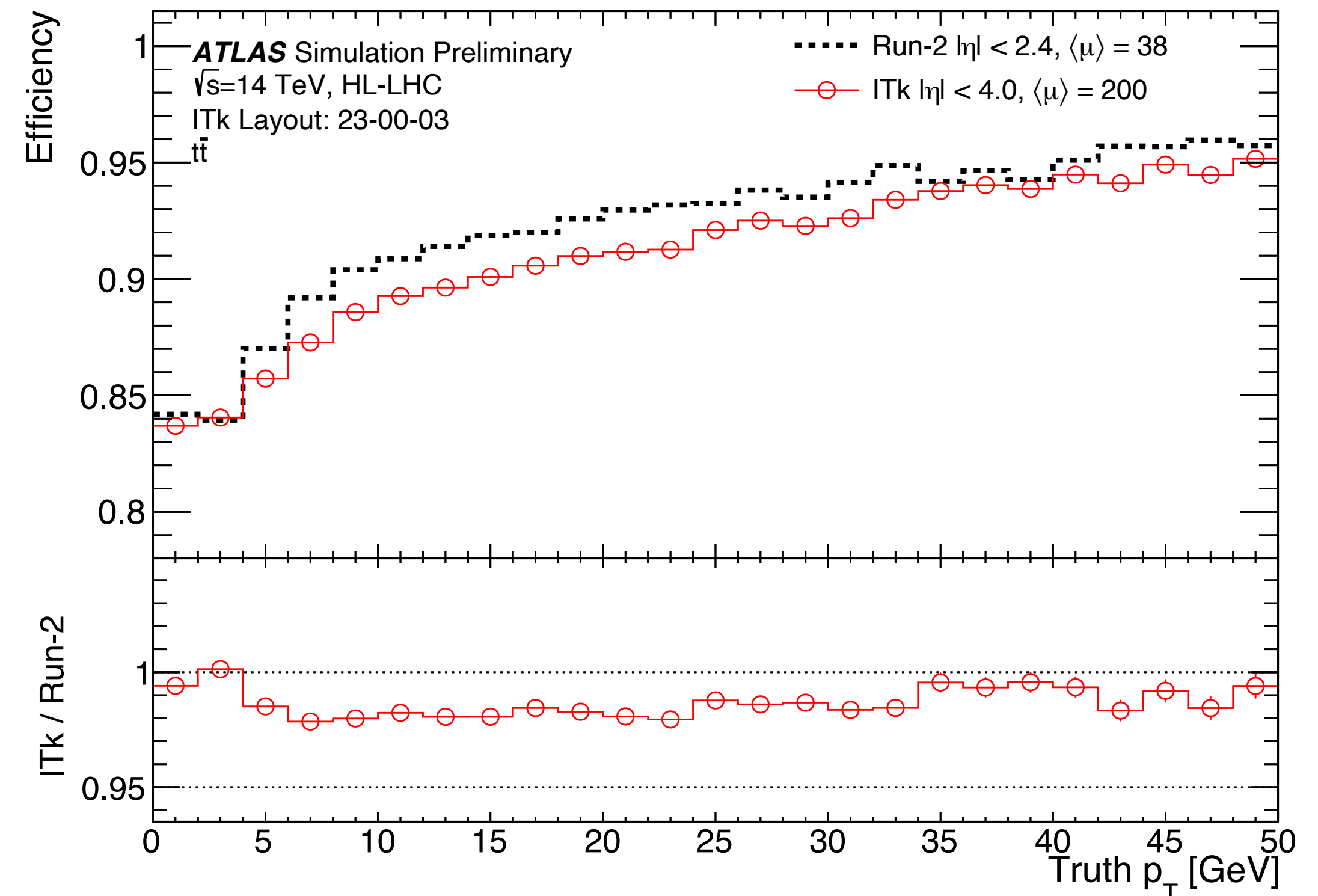
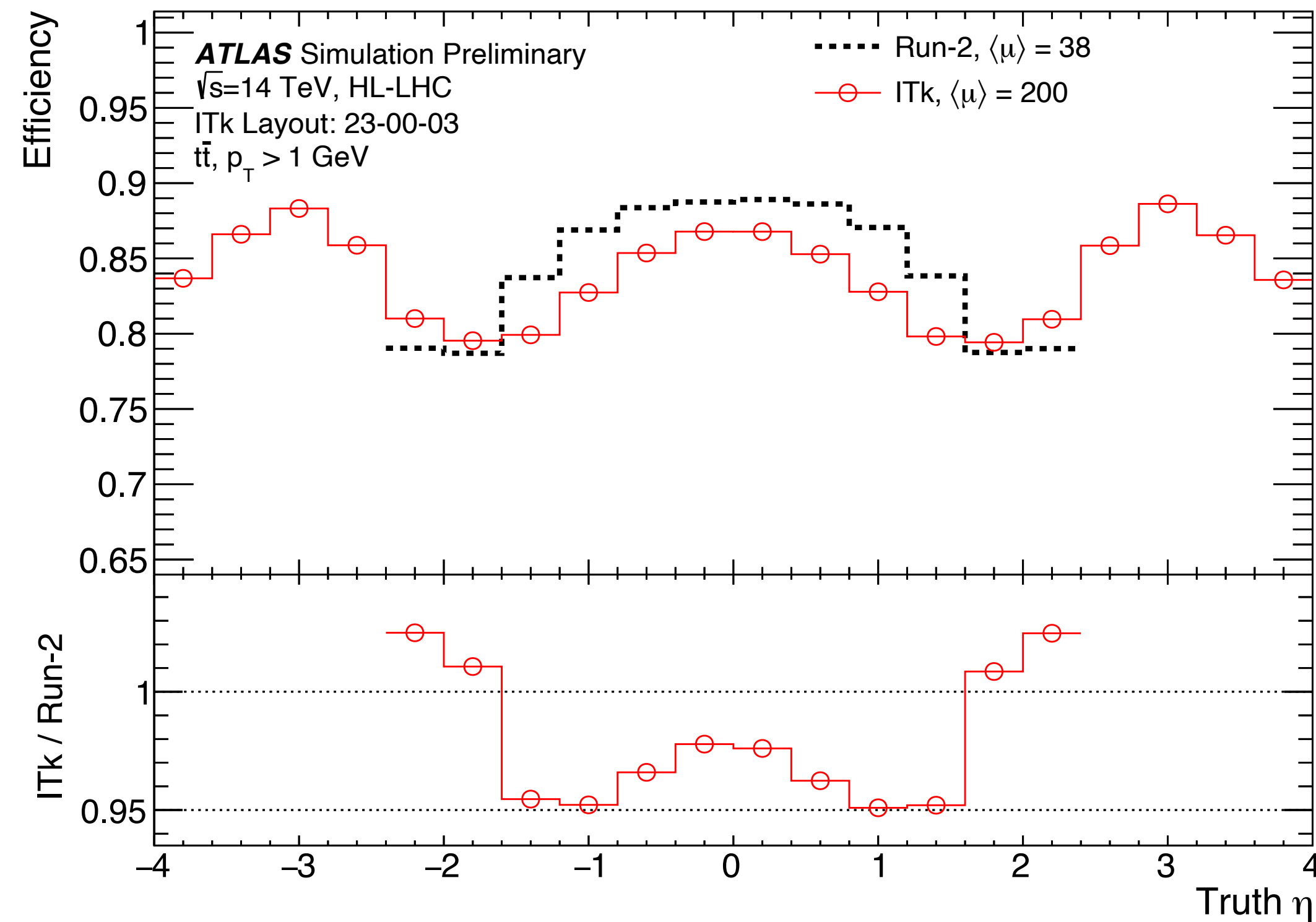


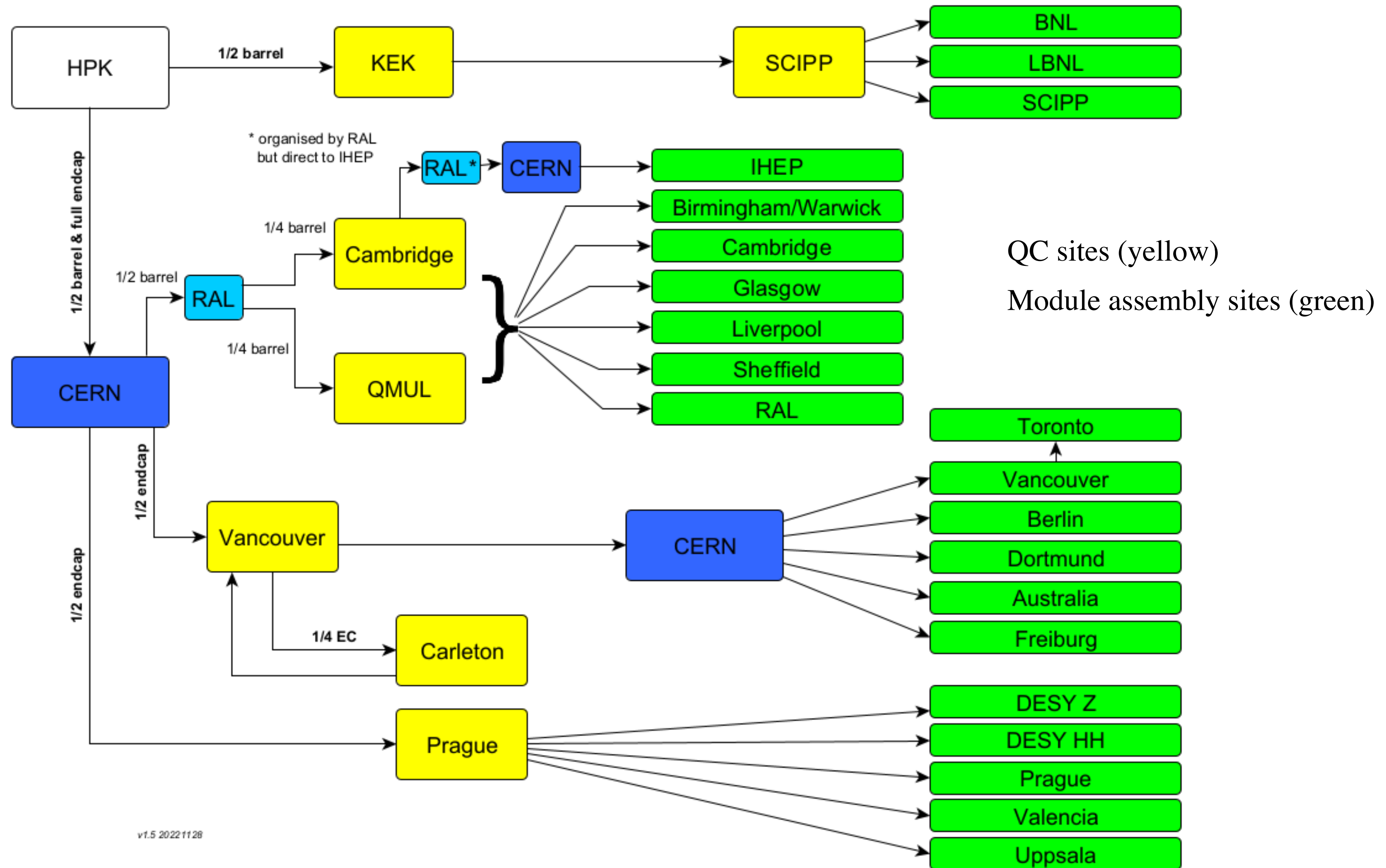
Figure 3.9: The fluence and dose distributions for the ITk layout. **Top:** The 1 MeV neutron equivalent flux. **Middle:** The total ionising dose. **Bottom:** The charged particle fluence.

The ITk expected performance



- Tracking efficiency for $t\bar{t}$ events at mean pile-up of 200
- Performance maintain although pile-up 5x more
- Extended performance up to 4 pseudo-rapidity with efficiency $>85\%$

ITk Strip Sensor part flow and QC procedure



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ITk Strip Sensor QC procedures

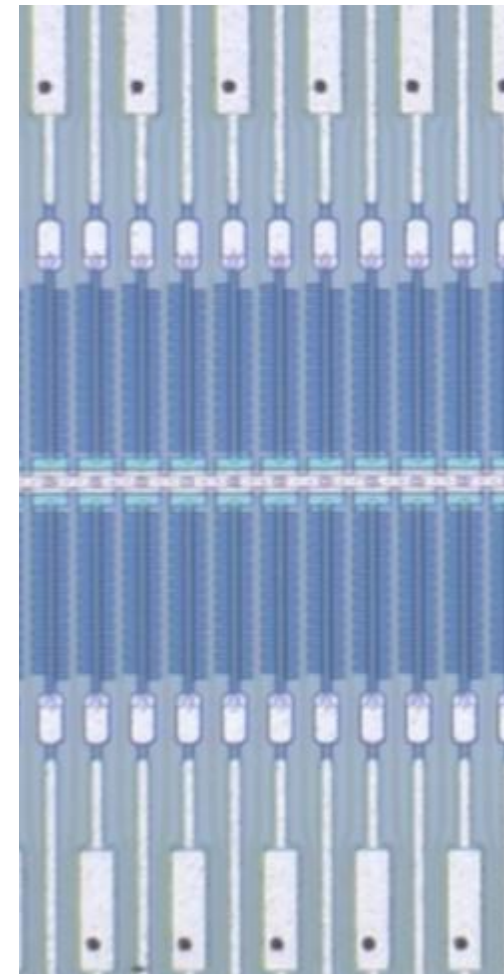
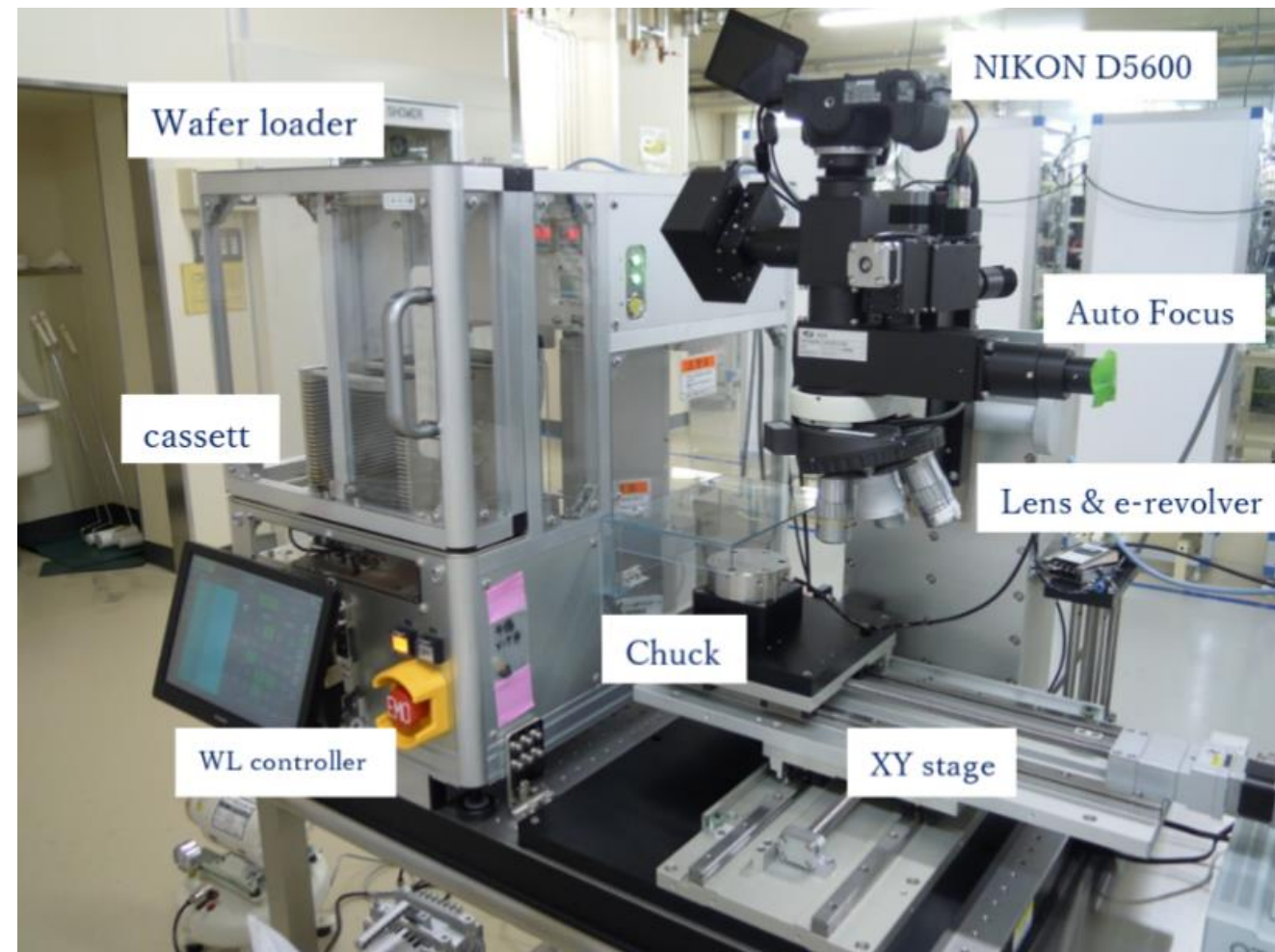


Figure 2. Metrology and Visual Capture setup installed in the clean laboratory of HPK and used by the KEK/Tsukuba QC testing site (left). Evidence of the resolution achieved with this setup (right).

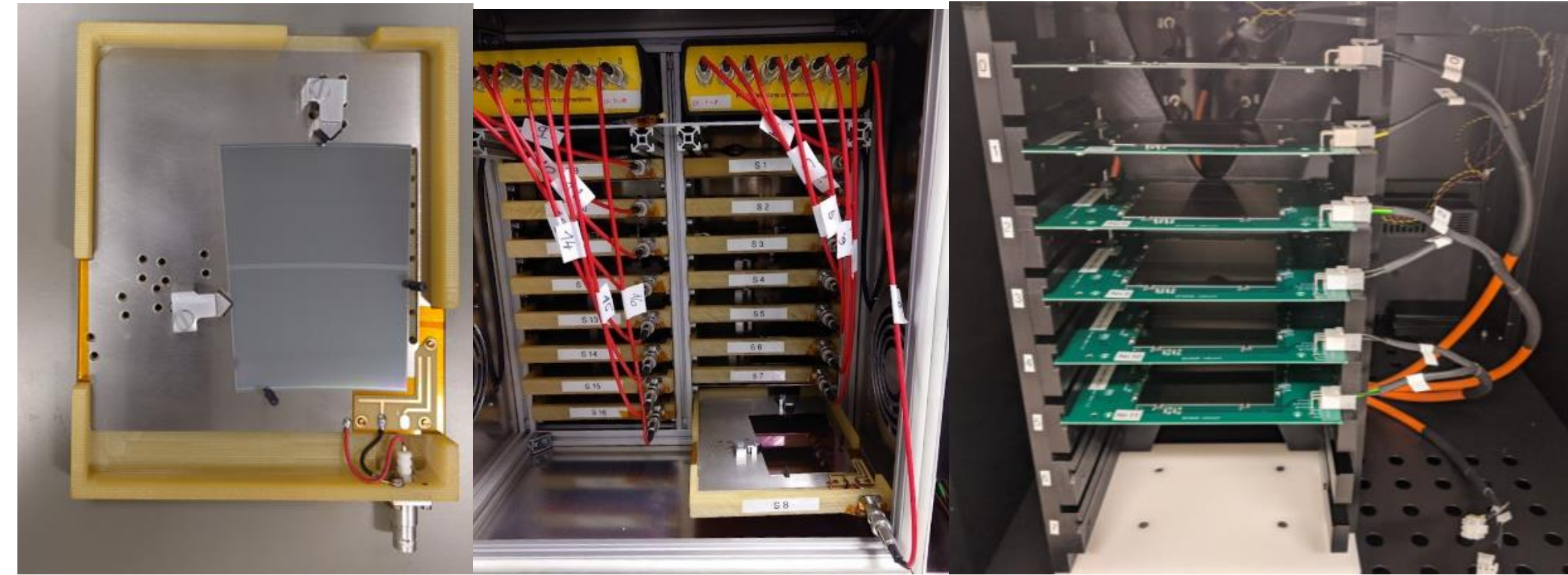


Figure 4. The R4 endcap sensor installed on the jig designed for leakage current stability tests (left). Dry storage cabinets with slots for sensor jigs or module test frames used for the leakage current stability tests in Prague (middle) and SCIPP (right).

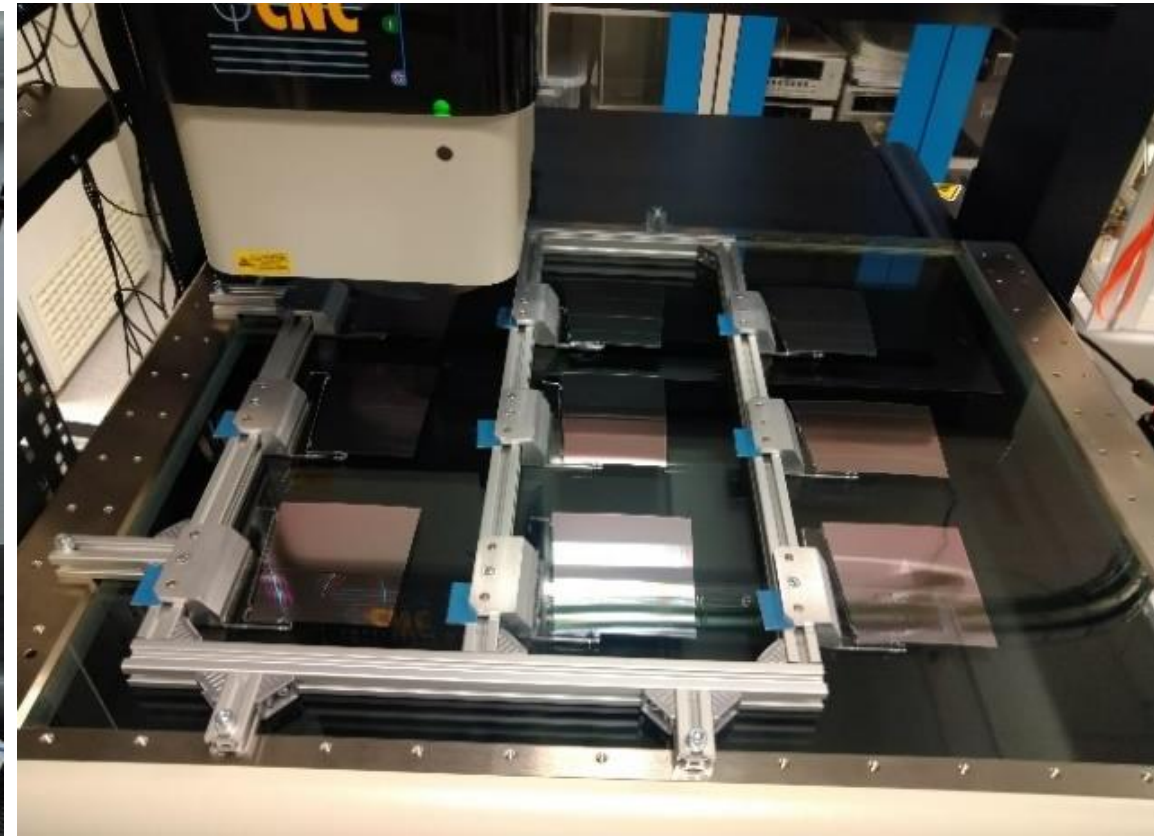


Figure 3. BATY Venture 3030 measurement system installed at University of Cambridge (left) and OGP SmartScope CNC 500 machine used for metrology and Visual Capture tests in Prague (right).

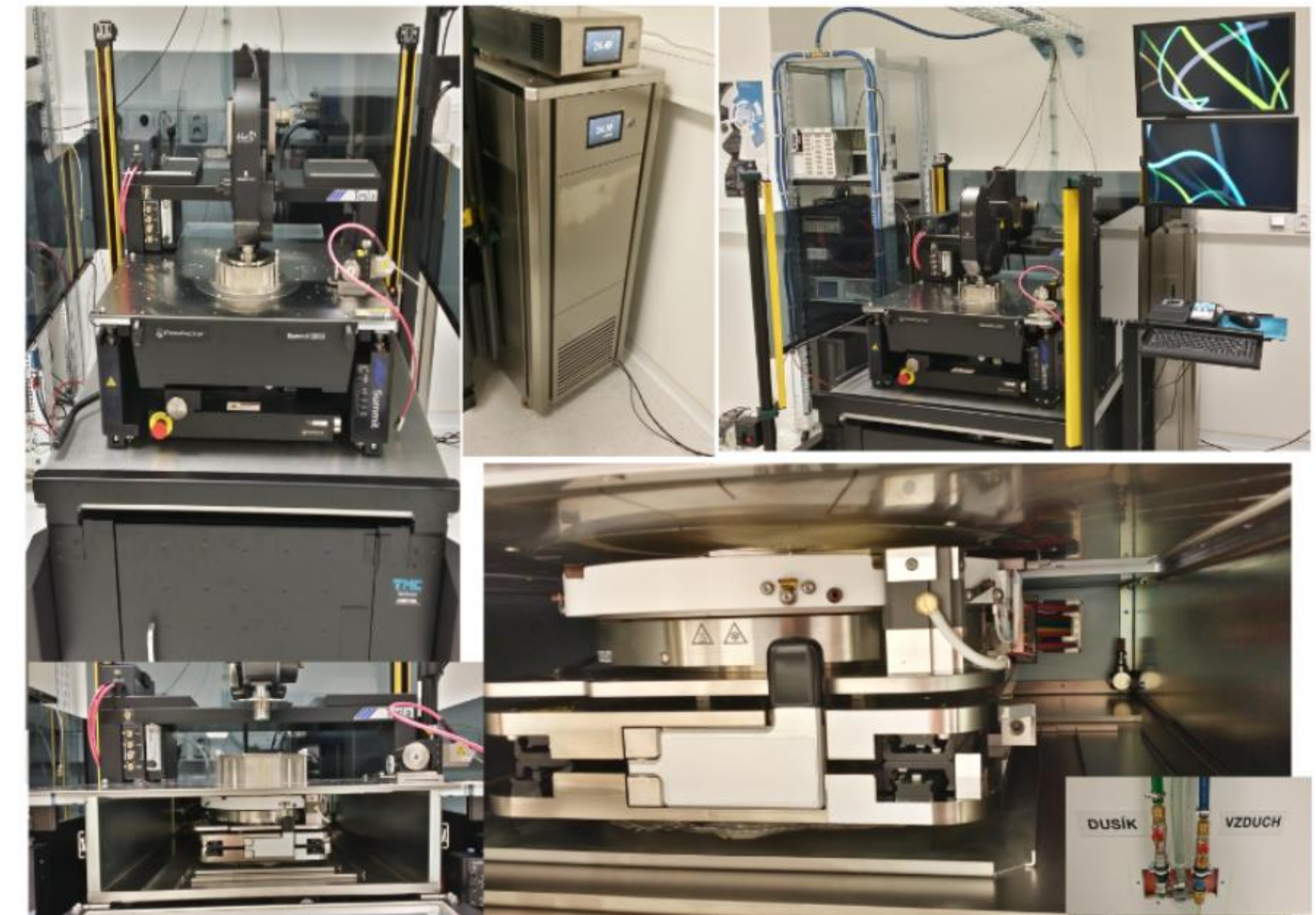
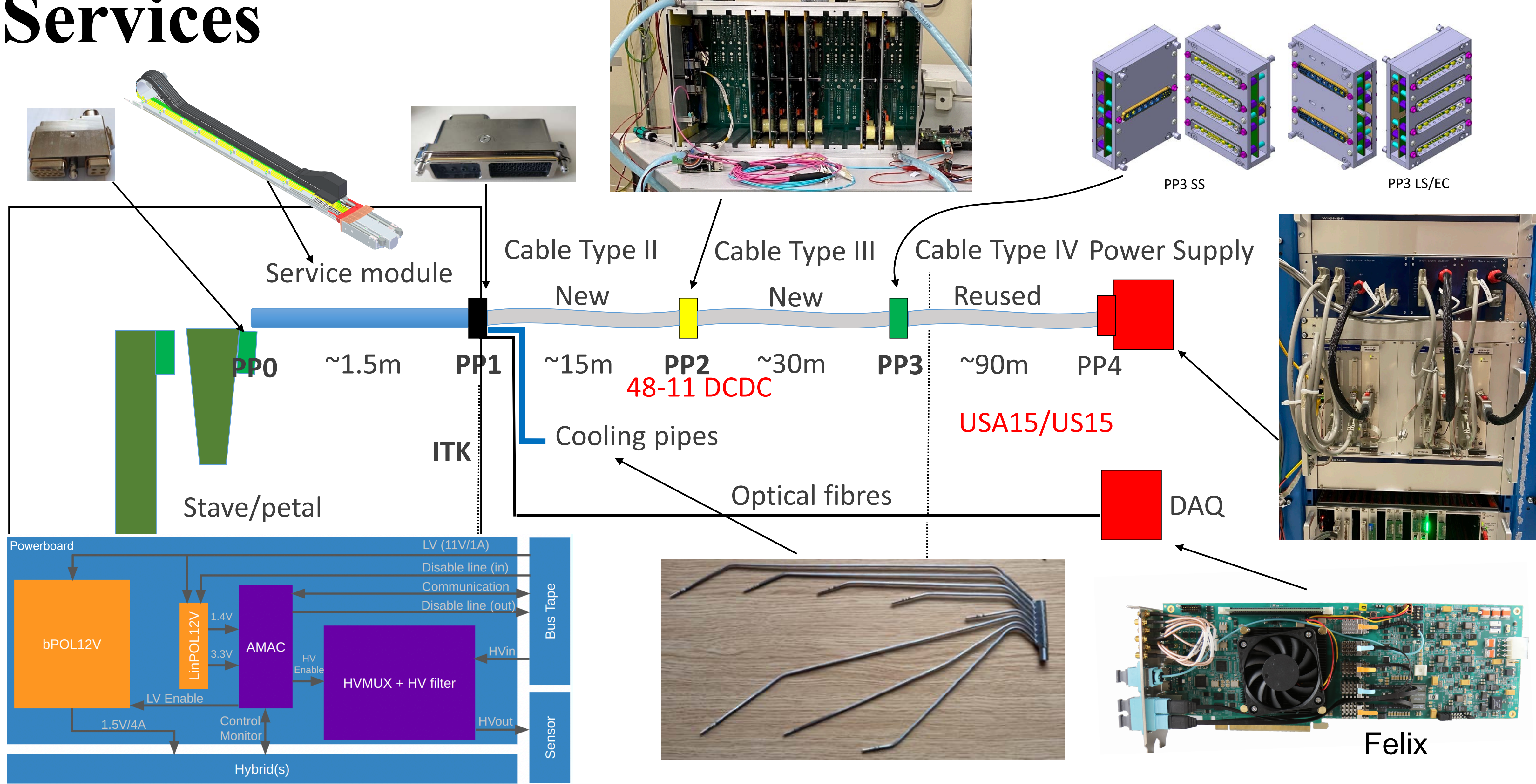


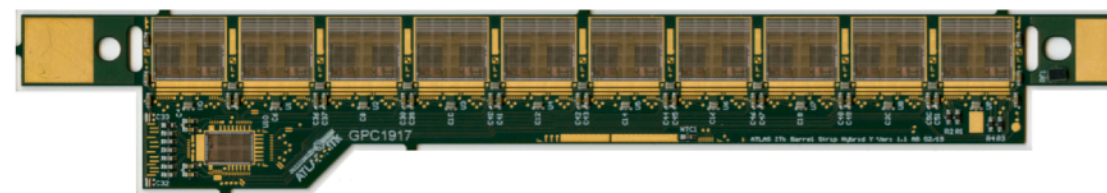
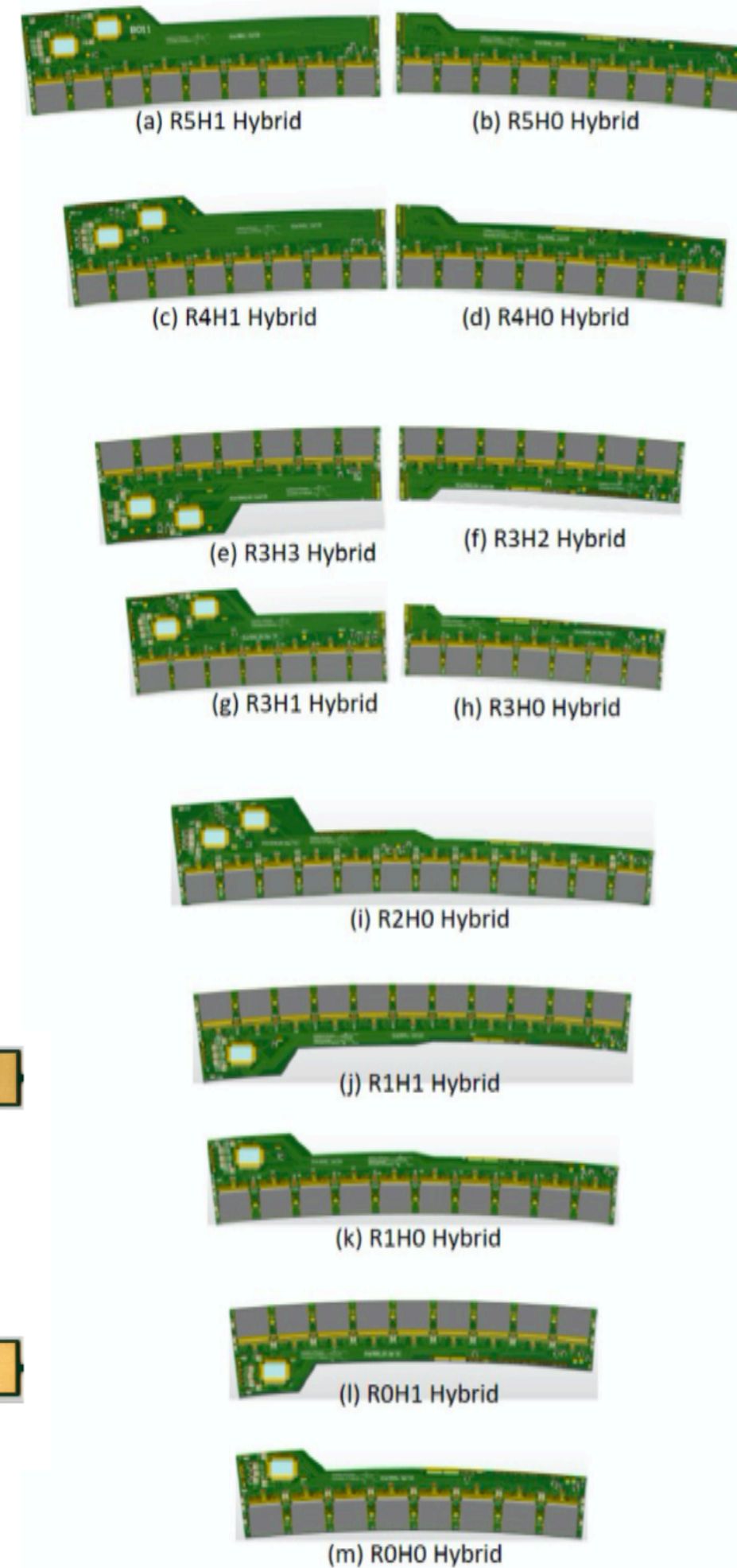
Figure 5. Semi-automatic Probe station Tesla 200mm installed in Prague.

Services

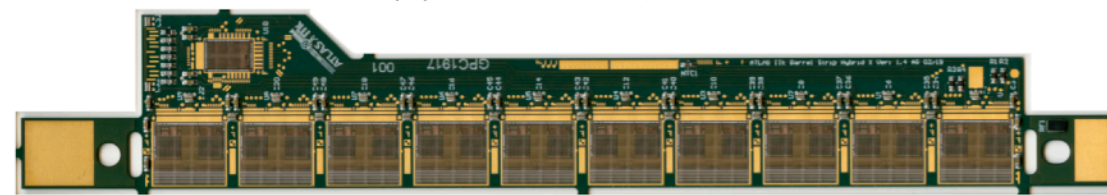


Hybrids

- ABCStar: ATLAS Binary Chip
- HCCStar: Hybrid Controller Chip



(a) Y barrel hybrid.



(b) X barrel hybrid.

